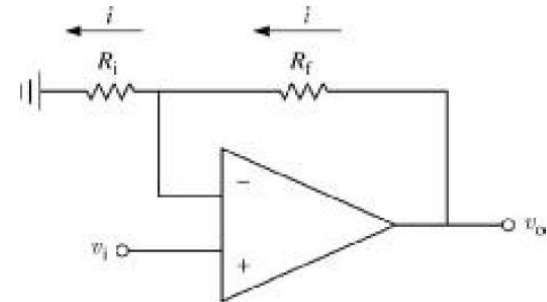




LAB #1: PRACTICAL ASPECTS OF OP AMP

Questions

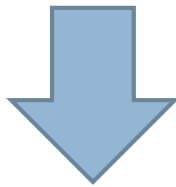
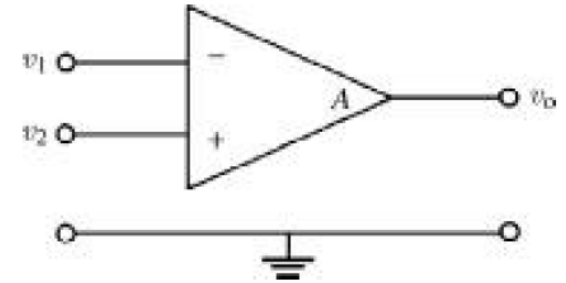
- What is the maximum gain for this circuit?
- What is the maximum output voltage range?
- Can we use it for any frequency?
- Are there any sources of error in the output?
- Can we choose any values for the resistances?
- What is the maximum power supply range that we can use?
- How to choose power supply range?
- How to select a suitable Op Amp for a particular application?



$$\frac{v_o}{v_i} = \frac{i(R_f + R_i)}{iR_i} = \frac{R_f + R_i}{R_i}$$

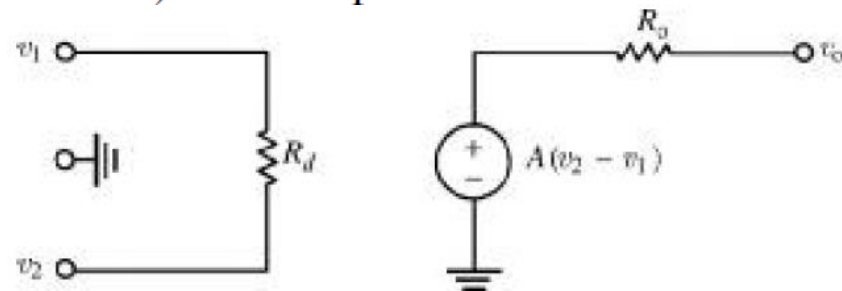
Ideal Op Amp Characteristics

1. $A = \infty$ (gain is infinity)
2. $v_o = 0$, when $v_1 = v_2$ (no offset voltage)
3. $R_d = \infty$ (input impedance is infinity)
4. $R_o = 0$ (output impedance is zero)
5. Bandwidth = ∞ (no frequency-response limitations) and no phase shift



$$v_+ = v_-$$

$$i_+ = i_- = 0$$



RULE 1 When the op-amp output is in its linear range, the two input terminals are at the same voltage.

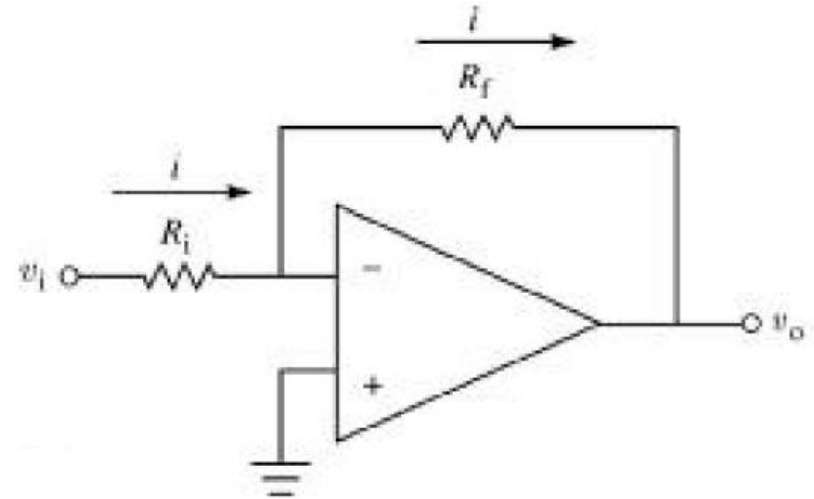
RULE 2 No current flows into either input terminal of the op amp.

Inverting Amplifier

$$v_o = -iR_f = -v_i \frac{R_f}{R_i}$$

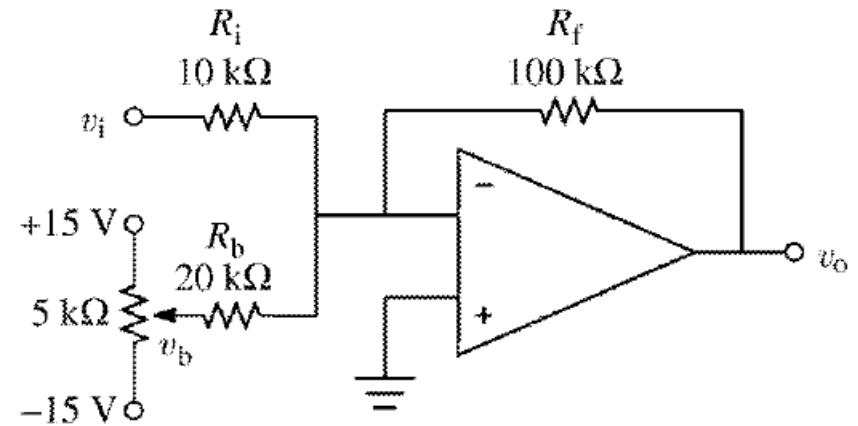


$$\frac{v_o}{v_i} = \frac{-R_f}{R_i}$$



Summing Amplifier

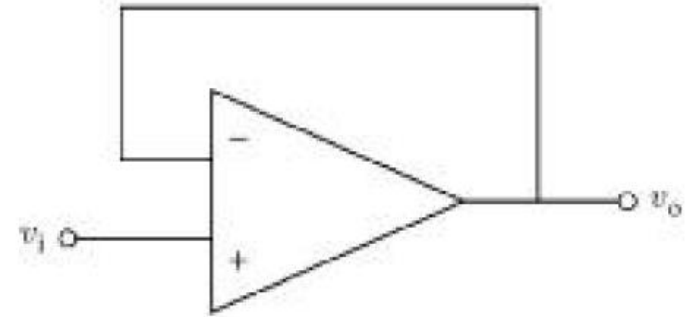
$$v_o = -R_f \left(\frac{v_i}{R_i} + \frac{v_b}{R_b} \right)$$



Voltage Follower

6

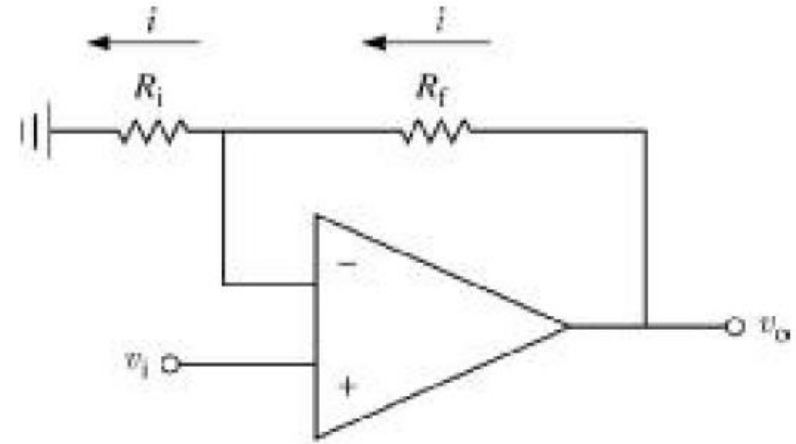
$$v_o = v_i$$



Noninverting Amplifier

7

$$\frac{v_o}{v_i} = \frac{i(R_f + R_i)}{iR_i} = \frac{R_f + R_i}{R_i}$$



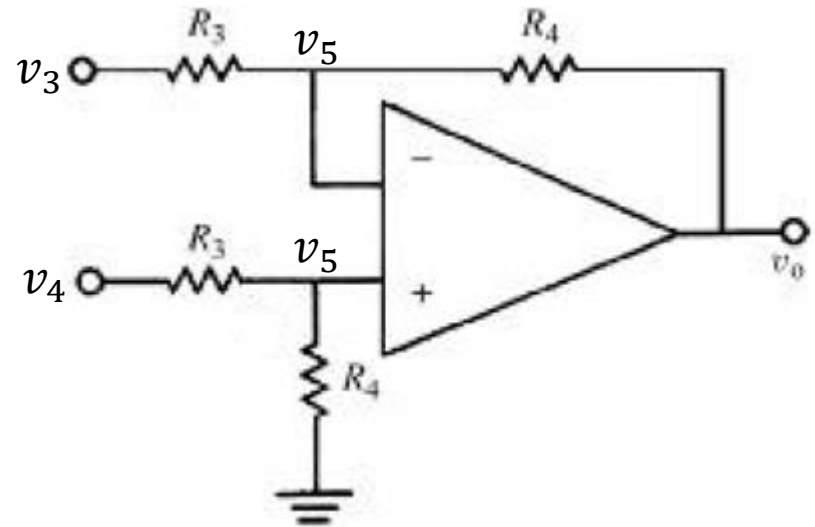
Differential Amplifier

$$v_5 = \frac{v_4 R_4}{R_3 + R_4}$$

$$i = \frac{v_3 - v_5}{R_3} = \frac{v_5 - v_o}{R_4}$$

$$v_o = \frac{(v_4 - v_3) R_4}{R_3}$$

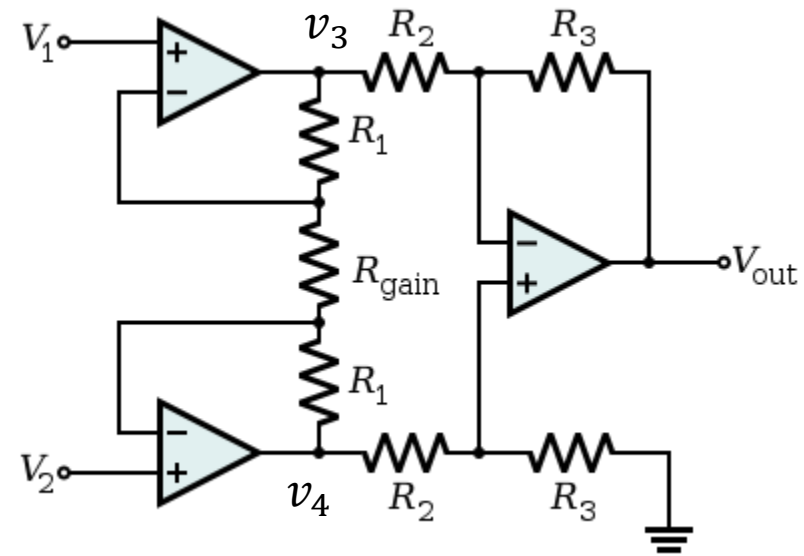
- Disadvantage: Low input impedance



Instrumentation Amplifier

$$v_3 - v_4 = (v_1 - v_2) / R_{gain} \cdot (2R_1 + R_{gain})$$

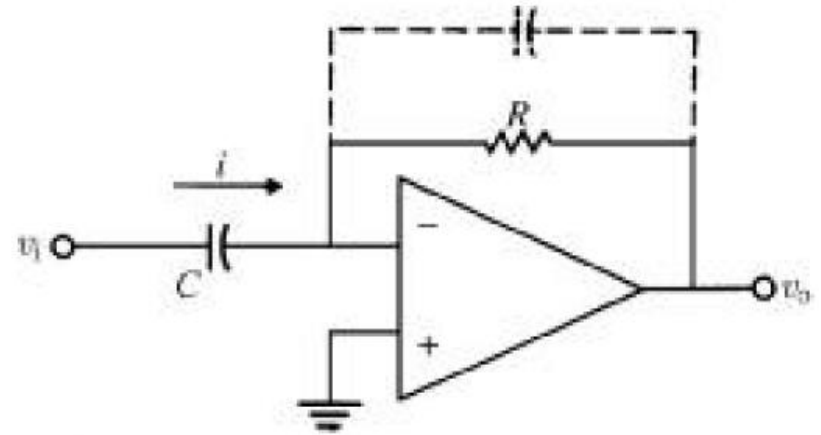
$$v_o = \frac{v_1 - v_2}{R_{gain}} \cdot (2R_1 + R_{gain})R_3/R_2$$



- Advantage: High input impedance

Differentiator

$$v_o = -RC \frac{dv_i}{dt}$$



Active Filters

Low-pass filter

$$\frac{V_o(j\omega)}{V_i(j\omega)} = -\frac{Z_f}{Z_i} = -\frac{(R_f/j\omega C_f)}{[(1/j\omega C_f) + R_f]}$$

$$= \frac{R_f}{(1 + j\omega R_f C_f)R_i} = -\frac{R_f}{R_i} \frac{1}{1 + j\omega\tau}$$

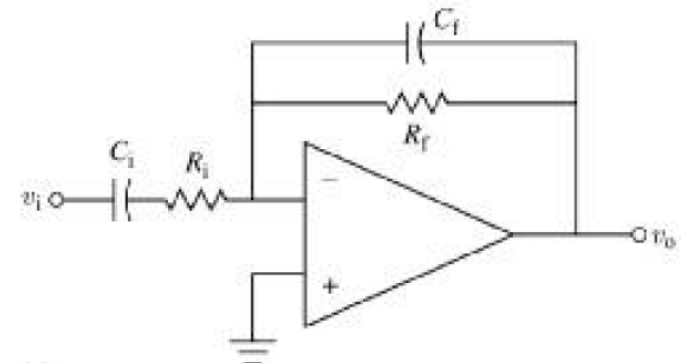
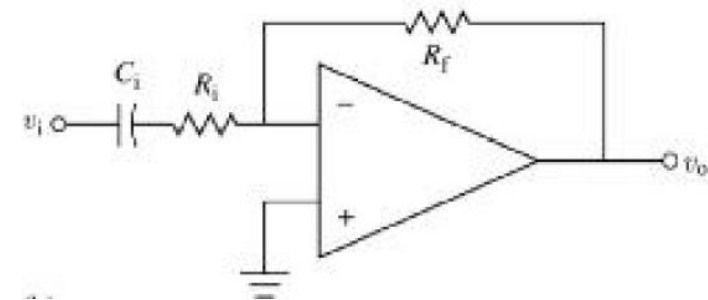
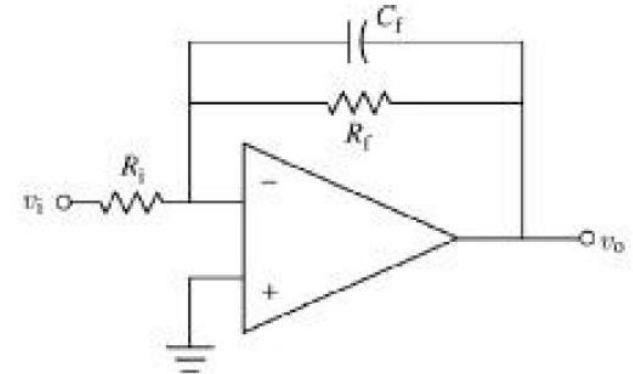
High-pass filter

$$\frac{V_o(j\omega)}{V_i(j\omega)} = -\frac{Z_f}{Z_i} = -\frac{R_f}{1/j\omega C_i + R_i}$$

$$= -\frac{j\omega R_f C_i}{1 + j\omega C_i R_i} = -\frac{R_f}{R_i} \frac{j\omega\tau}{1 + j\omega\tau}$$

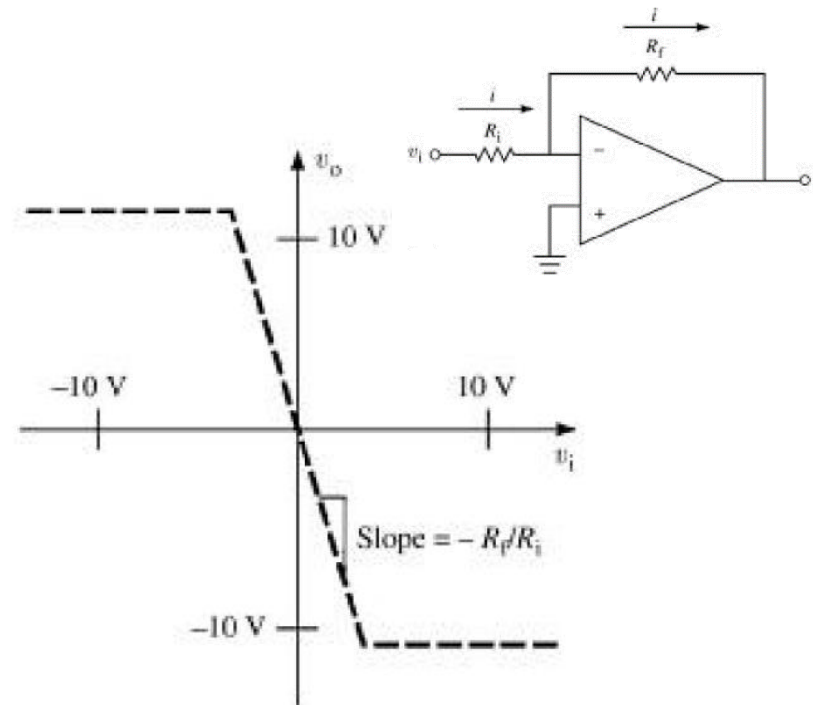
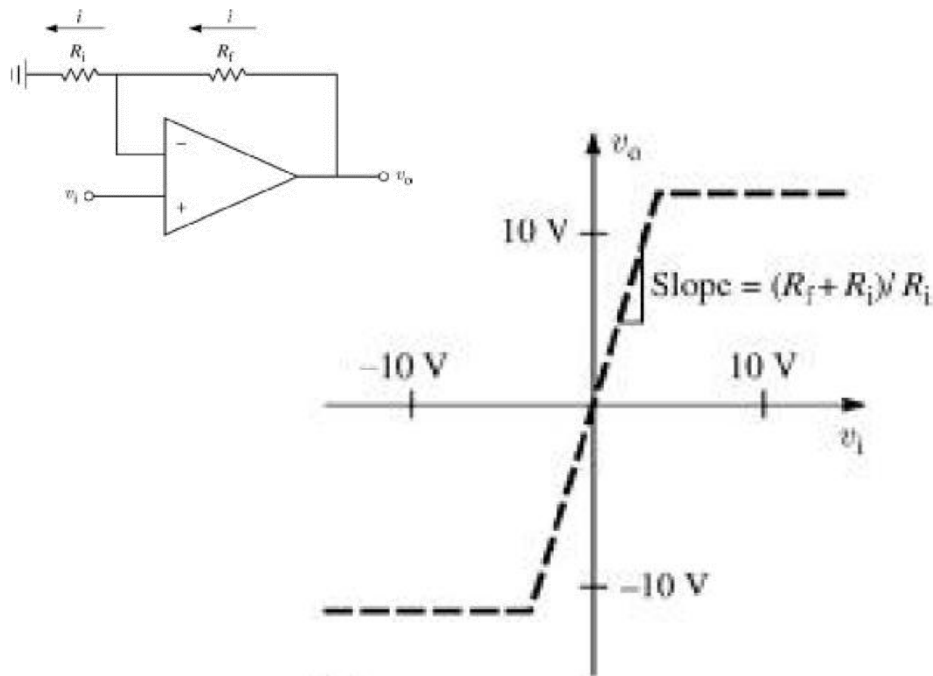
Band-pass filter

- Combination of the two



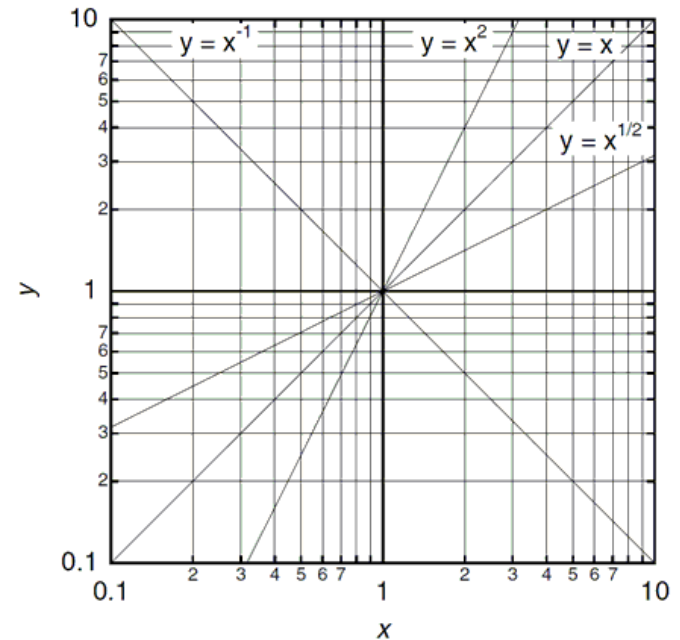
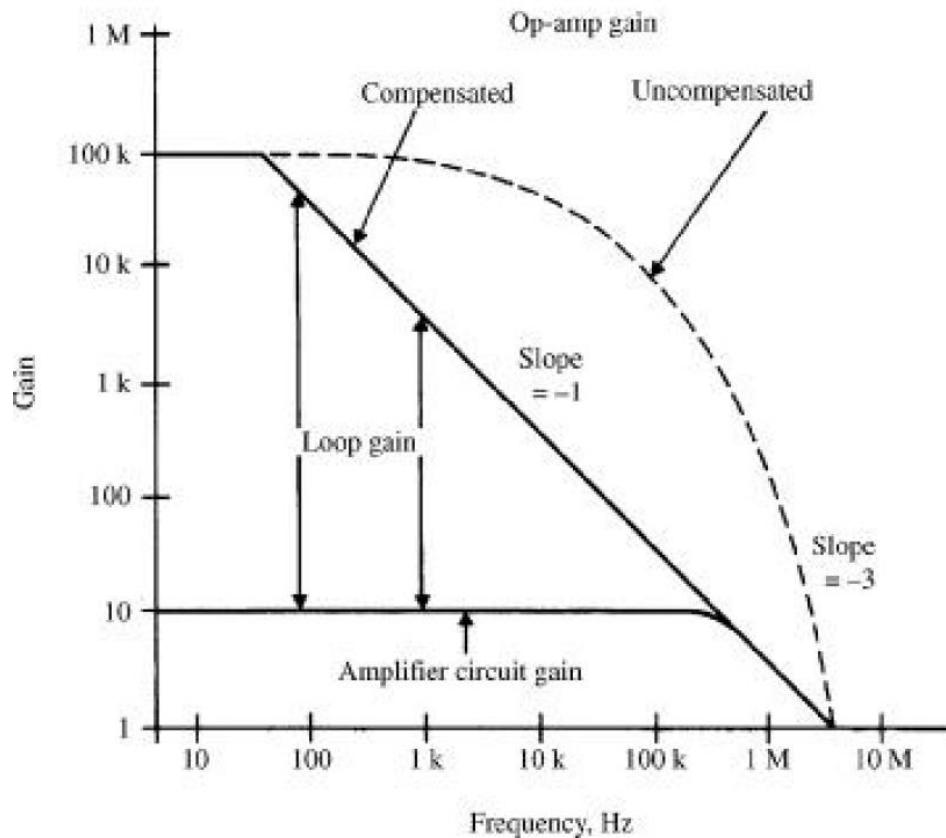
Practical Characteristics of Op Amps

- Linear range limitations
 - Depends on power supply range (slightly less)



Practical Characteristics of Op Amps

- Gain-Bandwidth Product = Constant for a given Op Amp
 - ▣ Evaluate using Log-Log plots

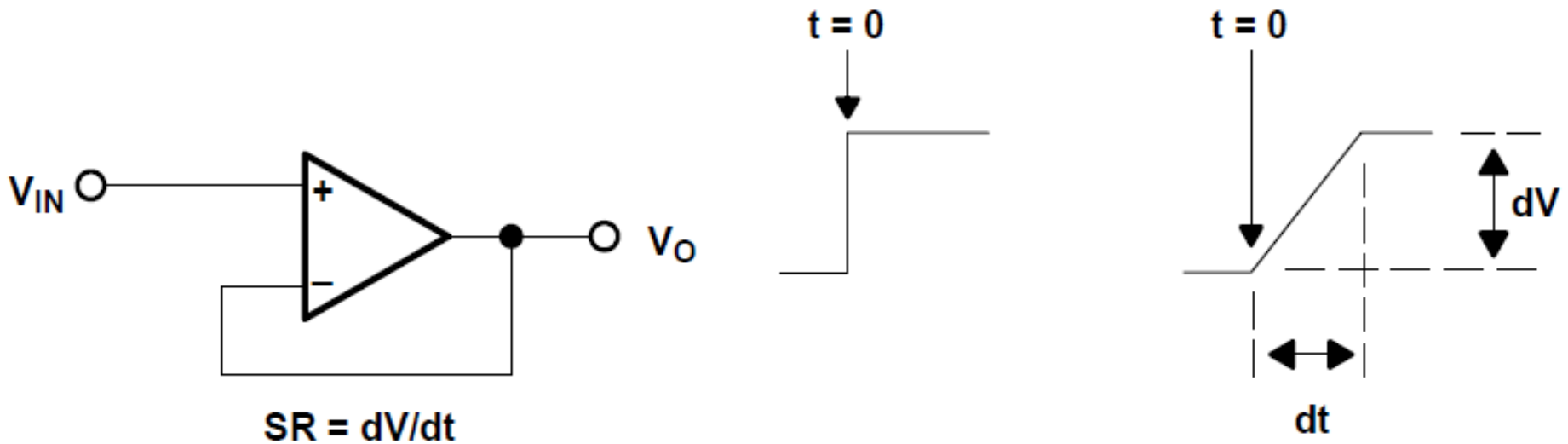


$$y = Bx^n$$

$$\log y = \log B + n \log x$$

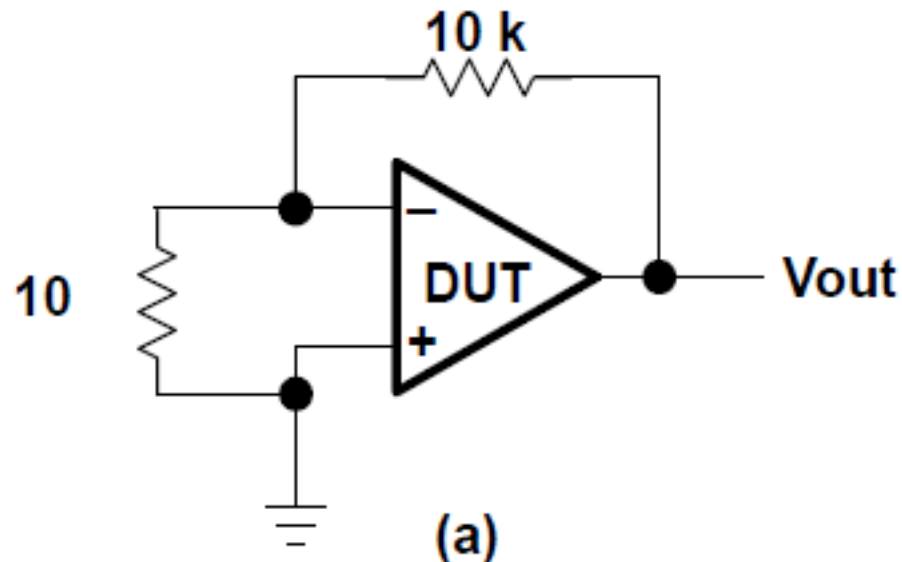
Practical Characteristics of Op Amps

□ Slew Rate



Practical Characteristics of Op Amps

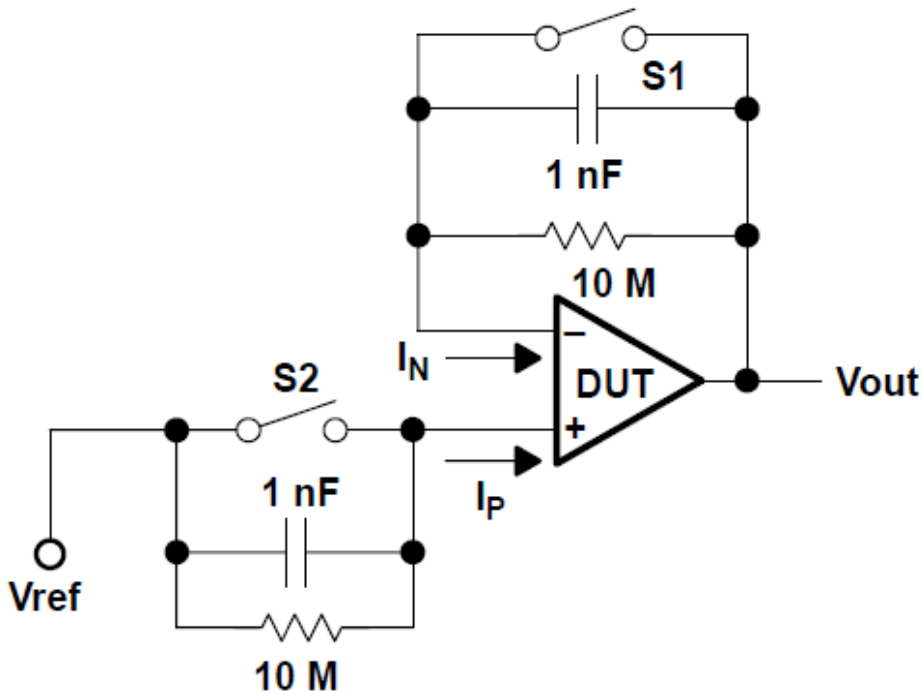
- Offset voltage
 - ▣ Small voltage between their inverting and noninverting inputs to balance mismatches due to unavoidable process variations
 - ▣ Input offset voltage is of concern anytime that DC accuracy is required of the circuit
 - ▣ Some Op Amps offer external offset nulling inputs



Practical Characteristics of Op Amps

□ Input bias current

- Input circuitry of all op amps requires a certain amount of bias current for proper operation
- Input bias current is of concern when the source impedance is high



S1 Closed

$$I_P = \frac{V_{out} - V_{ref}}{10^7}$$

S2 Closed

$$I_N = \frac{V_{out} - V_{ref}}{10^7}$$

$$I_{IB} = \frac{(I_N + I_P)}{2}$$

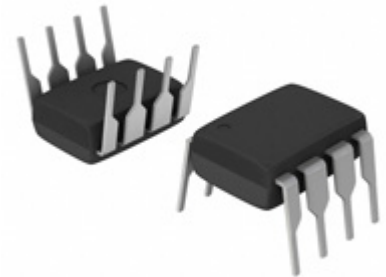
Example: 741 Op Amp



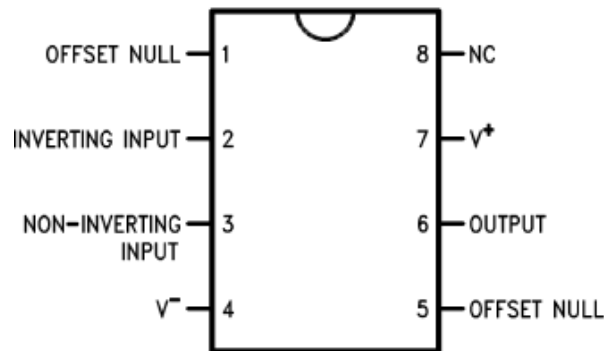
Bandwidth (Note 6)	1.5	MHz
Slew Rate	0.7	V/ μ s

LM741 Operational Amplifier

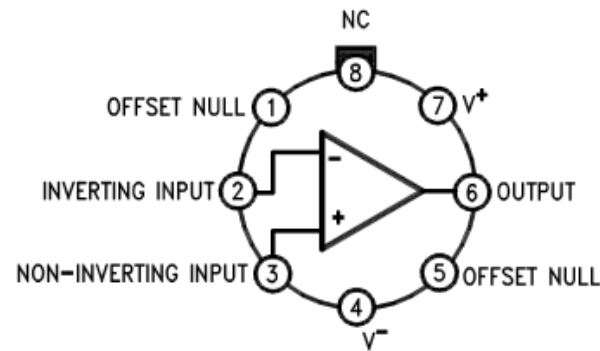
Output Voltage Swing	$V_S = \pm 20V$
----------------------	-----------------



Dual-In-Line or S.O. Package



Metal Can Package



Example: LH6702 Wideband Op Amp



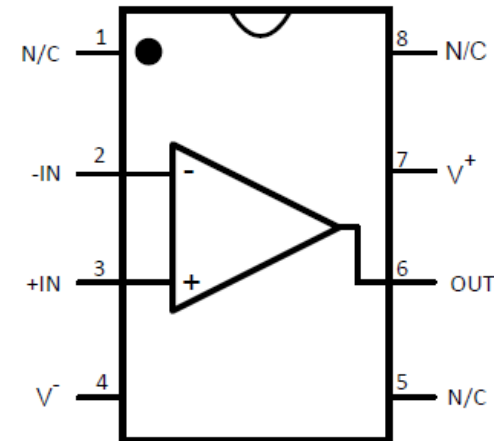
LMH6702

www.ti.com

SNOSA03F – NOVEMBER 2002 – REVISED MARCH 2013

LMH6702 1.7 GHz, Ultra Low Distortion, Wideband Op Amp

- **-3dB Bandwidth ($V_{OUT} = 0.5 V_{PP}$) 1.7 GHz**
- **Fast Slew Rate 3100V/ μ s**
- **Low Noise 1.83nV/ $\sqrt{\text{Hz}}$**



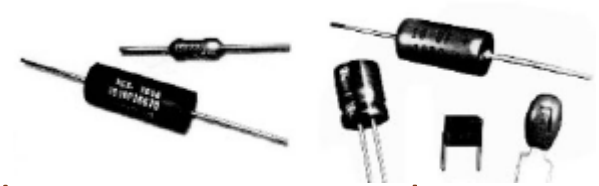
Basics of Electronic Components

- An electronic component is any device that handles electricity
- Electronic components come in many different shapes and sizes, and perform different electrical functions depending upon the purpose for which they are used
- Electronic equipment make use of a variety of components

Active vs. Passive Components

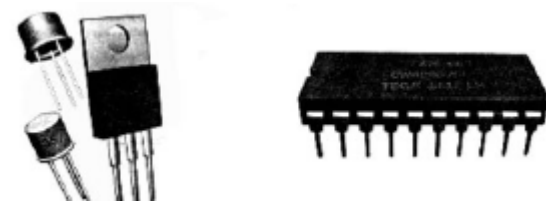
□ Passive

- ▣ One that contributes no power gain (amplification) to a circuit or system
- ▣ No control action and does not require any input other than a signal to perform its function



□ Active

- ▣ Capable of controlling voltages or currents and can create a switching action in the circuit
- ▣ Can amplify or interpret a signal

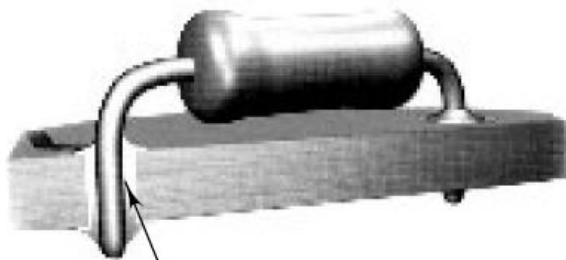


Discrete vs. Integrated Circuits

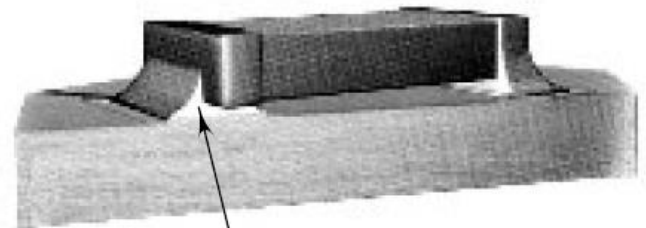
- When a component is packaged with one or two functional elements, it is known as a *discrete* component
 - ▣ Examples: resistors, inductors and capacitors
- An *integrated circuit* is a combination of several interconnected discrete components packaged in a single case to perform multiple functions
 - ▣ Examples: microprocessors and OP AMPs

Component Leads

- Two types on the basis of the method of their attachment to the circuit board
 - ▣ Through-hole components
 - ▣ Surface mount components



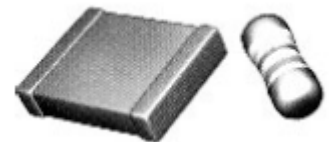
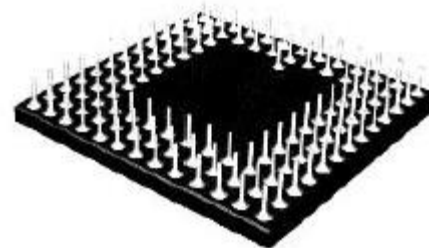
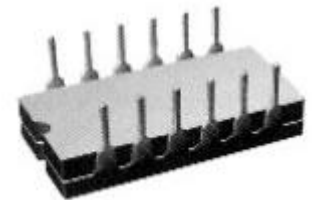
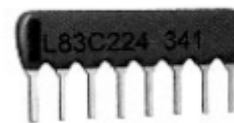
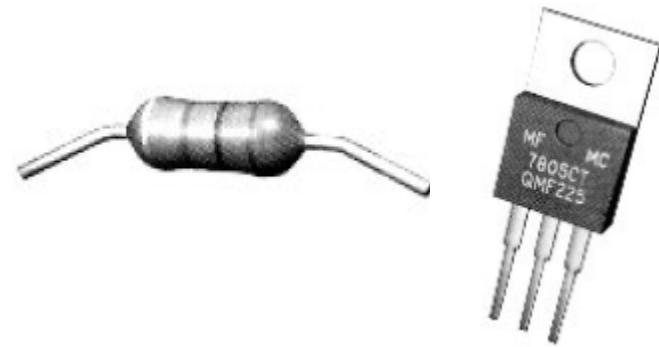
Cross-section of a through-hole solder joint



Cross-section of a surface mount solder joint

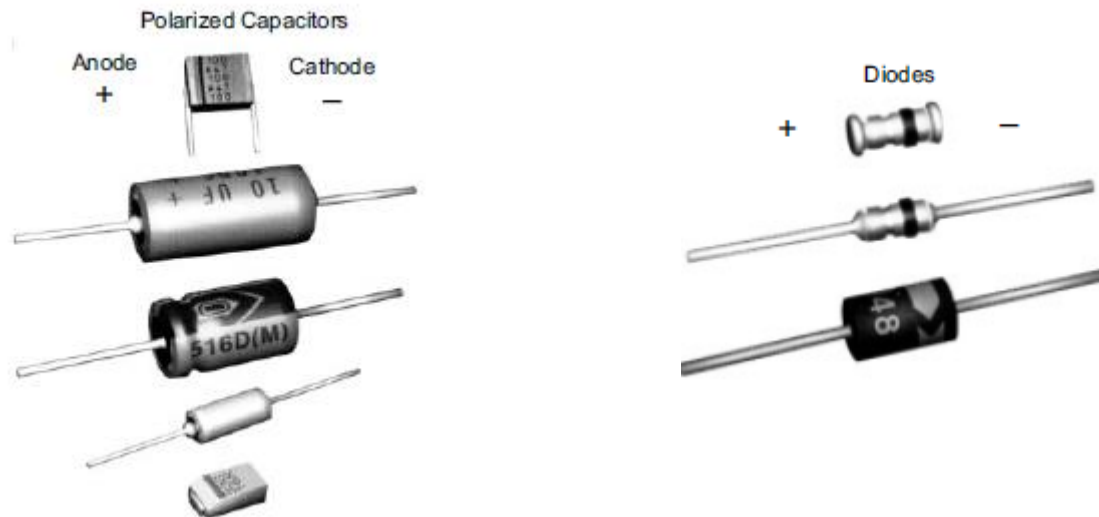
Component Leads: Examples

- ❑ Components with axial leads
- ❑ Components with radial leads
- ❑ Single-in-line package (SIL)
- ❑ Dual-inline package (DIP)
- ❑ Pin grid arrays (PGA)
- ❑ Ball grid arrays (BGA)
- ❑ Leadless components



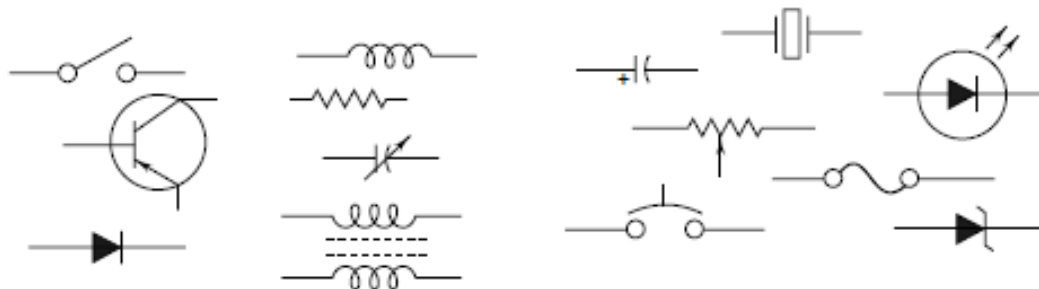
Polarity in Components

- Some components are polarized and therefore have leads which are marked with positive and negative polarity
 - ▣ Must be placed on the board in the correct orientation
 - ▣ Examples: electrolytic capacitors and diodes



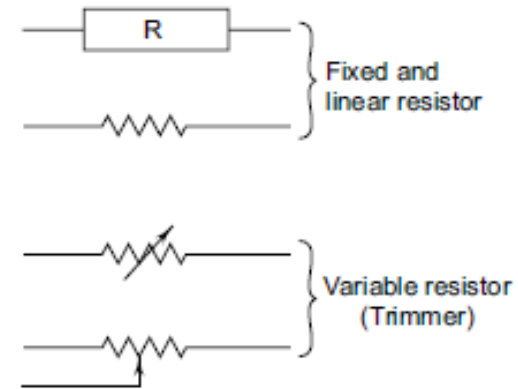
Component Symbols

- Each discrete component has a specific symbol when represented on a schematic diagram
 - ▣ Standardized and specified in the IEEE standard 315 and 315A (ANSI Y32.2)
- Integrated circuits are generally represented by a block in the schematic diagram
 - ▣ Do not have a specific symbol



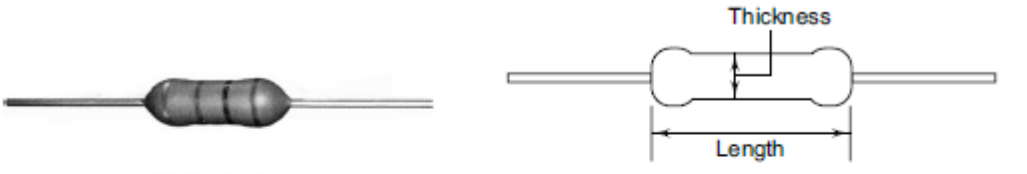
Resistors

- Fixed or variable
- Carbon
 - ▣ Good in high frequency
 - ▣ Limited accuracy to 1%
 - ▣ Drift with temperature and vibration
- Metal film
 - ▣ stable under temperature and vibration
 - ▣ Reach accuracies of 0.1% in precision films
- Wire-wound Resistors
 - ▣ Very high accuracy possible



Resistors: Examples

Carbon film



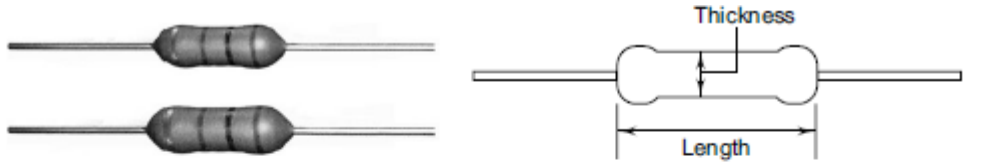
From the top of the photograph
 1/8W
 1/4W
 1/2W

Thickness
 Length

Approximate size

Rating power (W)	Thickness (mm)	Length (mm)
1/8	2	3
1/4	2	6
1/2	3	9

Metal Film



From the top of the photograph
 1/8W (tolerance $\pm 1\%$)
 1/4W (tolerance $\pm 1\%$)
 1W (tolerance $\pm 5\%$)
 2W (tolerance $\pm 5\%$)

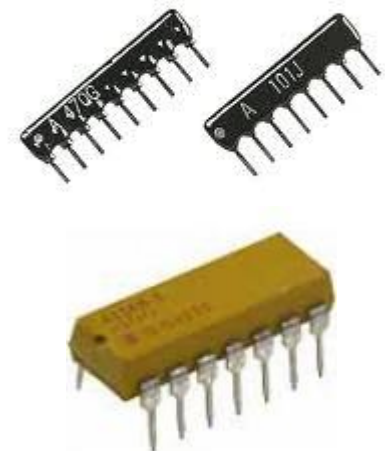
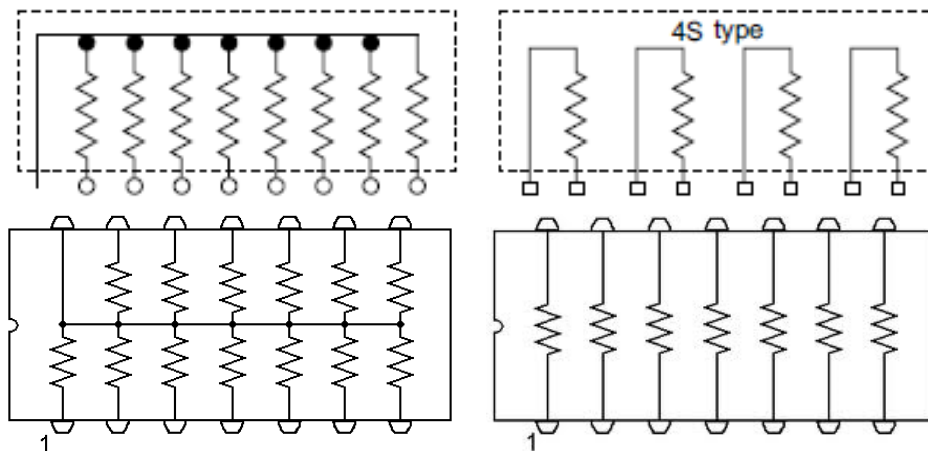
Thickness
 Length

Approximate size

Rating power (W)	Thickness (mm)	Length (mm)
1/8	2	3
1/4	2	6
1	3.5	12
2	5	15

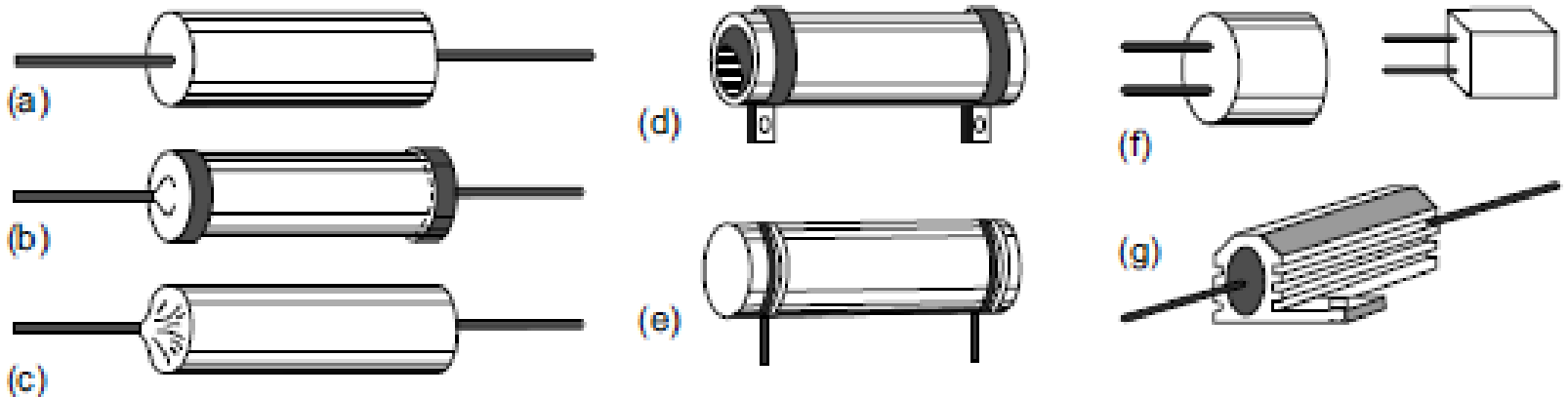
Resistors: Thick Film Networks

- precious metals in a glass binding system which have been screened on to a ceramic substrate and fired at high temperatures
 - ▣ Miniaturization and rugged construction
 - ▣ Inherently reliable, not subject to catastrophic failures
 - ▣ SIL or DIP packages



Resistors: Packages

- (a),(b),(c) Cylindrical package with axial leads
- (d), (e) Cylindrical package with radial leads
- (f) radial package with radial lead
- (g) high-power package, with axial leads and copper body for increased heat dissipation



Resistors: Characteristics

- Resistance
- Tolerance
- Power Rating
- Temperature Coefficient (hot spot temperature)
- Stability or Drift
- Noise
- Parasitic Effects
- Maximum Voltage
- Identification

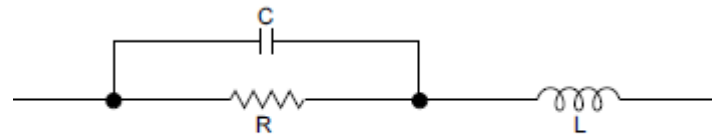


Fig. 2.10 Lumped model of a resistor $C = 0.1\text{-}2\text{ pf}$, $L = 0.1\text{ }\mu\text{H}$
(for a leaded component)

Resistors: Values

Code

F = $\pm 1\%$

G = $\pm 2\%$

j = $\pm 5\%$

K = $\pm 10\%$

M = $\pm 20\% \pm$

R 68M is a $0.68 \Omega \pm 20\%$ resistor

5K 6J is a $5.6 \text{ k}\Omega \pm 5\%$ resistor

82KK is $82 \text{ k}\Omega \pm 10\%$ resistor


Preferred range:

- E 12 series (common): 10, 12, 15, 18, 22, 27, 33, 39, 47, 56, 68, 82

- E 96 series: for $\pm 1\%$


Four Band Resistors

1 st Band		2 nd Band		3 rd Band		4 th Band (tolerance)						
Black	0	Black	0	Silver	Divide by 100		<table border="1"> <tr><td>Red</td><td>$\pm 2\%$</td></tr> <tr><td>Gold</td><td>$\pm 5\%$</td></tr> <tr><td>Silver</td><td>$\pm 10\%$</td></tr> </table>	Red	$\pm 2\%$	Gold	$\pm 5\%$	Silver
Red	$\pm 2\%$											
Gold	$\pm 5\%$											
Silver	$\pm 10\%$											
Brown	1	Brown	1	Gold	Divide by 10							
Red	2	Red	2	Black	Multiply by 1							
Orange	3	Orange	3	Brown	Multiply by 10							
Yellow	4	Yellow	4	Red	Multiply by 100							
Green	5	Green	5	Orange	Multiply by 1,000							
Blue	6	Blue	6	Yellow	Multiply by 10,000							
Violet	7	Violet	7	Green	Multiply by 100,000							
Grey	8	Grey	8	Blue	Multiply by 1,000,000							
White	9	White	9									



Five Band Resistors

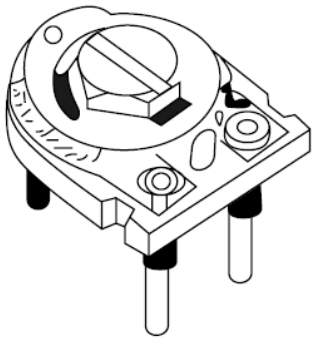
1 st Band		2 nd Band		3 rd Band		4 th Band		5 th Band (tolerance)								
Black	0	Black	0	Black	0	Silver	Divide by 100		<table border="1"> <tr><td>Brown</td><td>$\pm 1\%$</td></tr> <tr><td>Red</td><td>$\pm 2\%$</td></tr> <tr><td>Gold</td><td>$\pm 5\%$</td></tr> <tr><td>Silver</td><td>$\pm 10\%$</td></tr> </table>	Brown	$\pm 1\%$	Red	$\pm 2\%$	Gold	$\pm 5\%$	Silver
Brown	$\pm 1\%$															
Red	$\pm 2\%$															
Gold	$\pm 5\%$															
Silver	$\pm 10\%$															
Brown	1	Brown	1	Brown	1	Gold	Divide by 10									
Red	2	Red	2	Red	2	Black	Multiply by 1									
Orange	3	Orange	3	Orange	3	Brown	Multiply by 10									
Yellow	4	Yellow	4	Yellow	4	Red	Multiply by 100									
Green	5	Green	5	Green	5	Orange	Multiply by 1,000									
Blue	6	Blue	6	Blue	6	Yellow	Multiply by 10,000									
Violet	7	Violet	7	Violet	7	Green	Multiply by 100,000									
Grey	8	Grey	8	Grey	8	Blue	Multiply by 1,000,000									
White	9	White	9	White	9											



Variable Resistors or Potentiometers

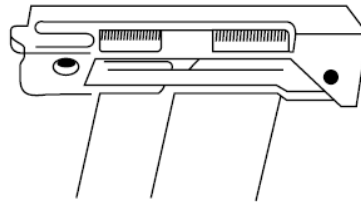
- “Pots” consist of a track of some type of resistance material with which a movable wiper makes contact
- 3 Categories: (a) Carbon (b) Cermet (c) Wire wound

Skeleton trimmer (carbon)

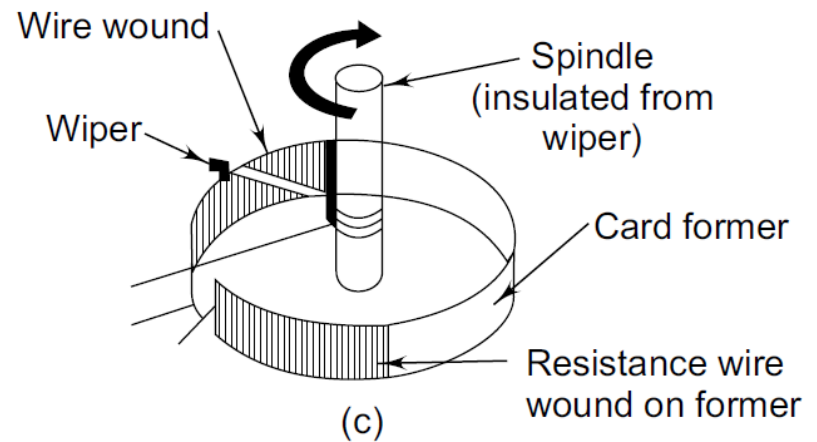


(a)

Cermet multi-turn pot



(b)



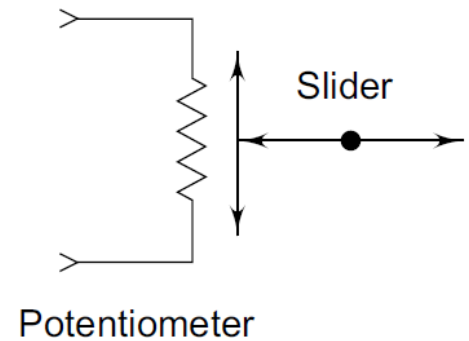
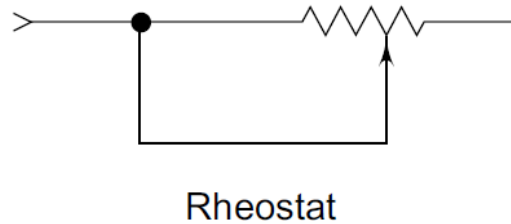
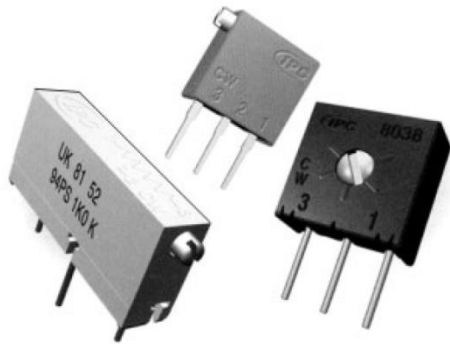
(c)

Variable Resistors or Potentiometers

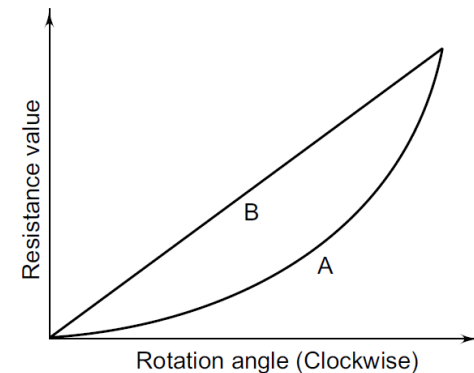
- Pots can be categorized into the following types depending upon the number of resistors and control arrangement used:
 - ▣ *Single Potentiometers*: Pot control with one resistor
 - ▣ *Tandem Potentiometers*: Two identical resistor units controlled by one spindle
 - ▣ *Twin Potentiometers*: Two resistor units controlled by two independent concentric spindles
 - ▣ *Multi-turn Potentiometers*: Potentiometer with knob or gear wheel for resistance adjustment; they may have up to 40 rotations of spindle
 - ▣ *Potpack*: Rectangular pots, either single or multi-turn

Variable Resistors or Potentiometers

- Variable resistor can be used either as a rheostat or potentiometer

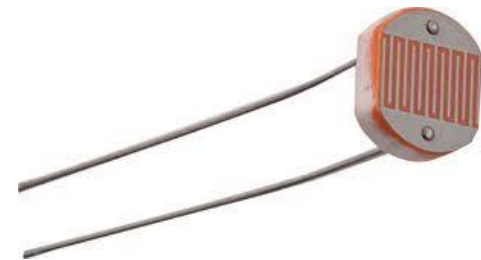


- Construction resistance laws:
 - Linear
 - Logarithmic
 - Sine-Cosine



Light-dependent Resistors (LDRs)

- Made of cadmium sulphide and contain very few free electrons
 - ▣ When kept in complete darkness and therefore, exhibit very high resistance.
 - ▣ When in light, electrons are liberated and the material becomes more conducting.
- Typical dark resistance of LDRs is 1-10 MOhms.
- Typical light resistance is 75 -300 ohms.
- LDRs take some finite time to change its state and this time is called the recovery time.
 - ▣ Typical recovery rate is 200 kOhms/sec.



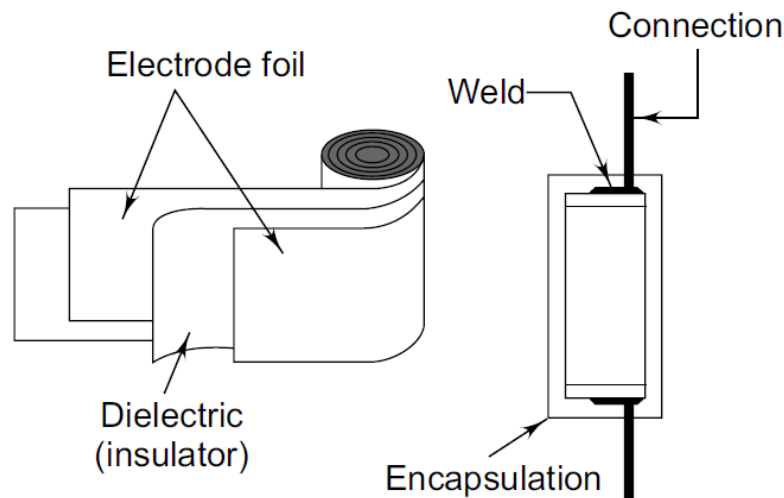
Thermistors

- Resistors with high temperature co-efficient of resistance
- Two types:
 - ▣ Positive temperature coefficient (PTC)
 - ▣ Negative temperature coefficient (NTC) (most popular)
- Available in a wide variety of shapes and forms suitable for use in different applications.
- Inherently nonlinear resistance–temperature curve
 - ▣ Can be linearized by proper circuit

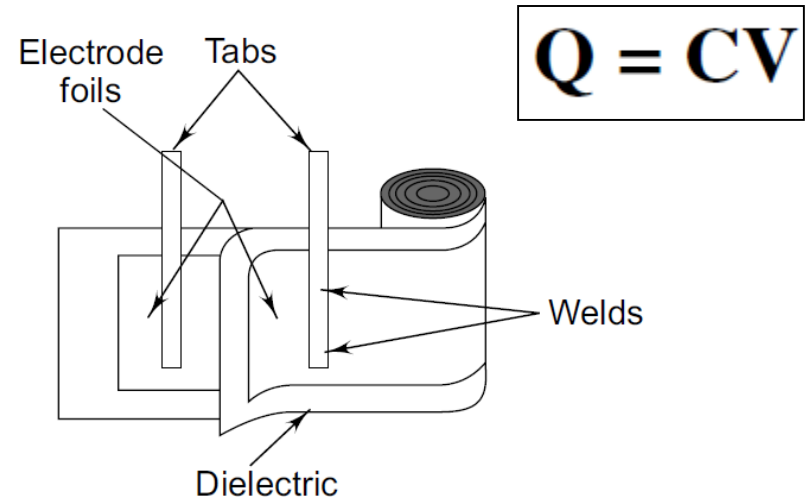


Capacitors (Condensers)

- Passive component that can be used to store electrical charge – measured in Farads (F)
- Consists of two facing conductive plates called electrodes, which are separated by a dielectric or insulator



(a) Extended foil type

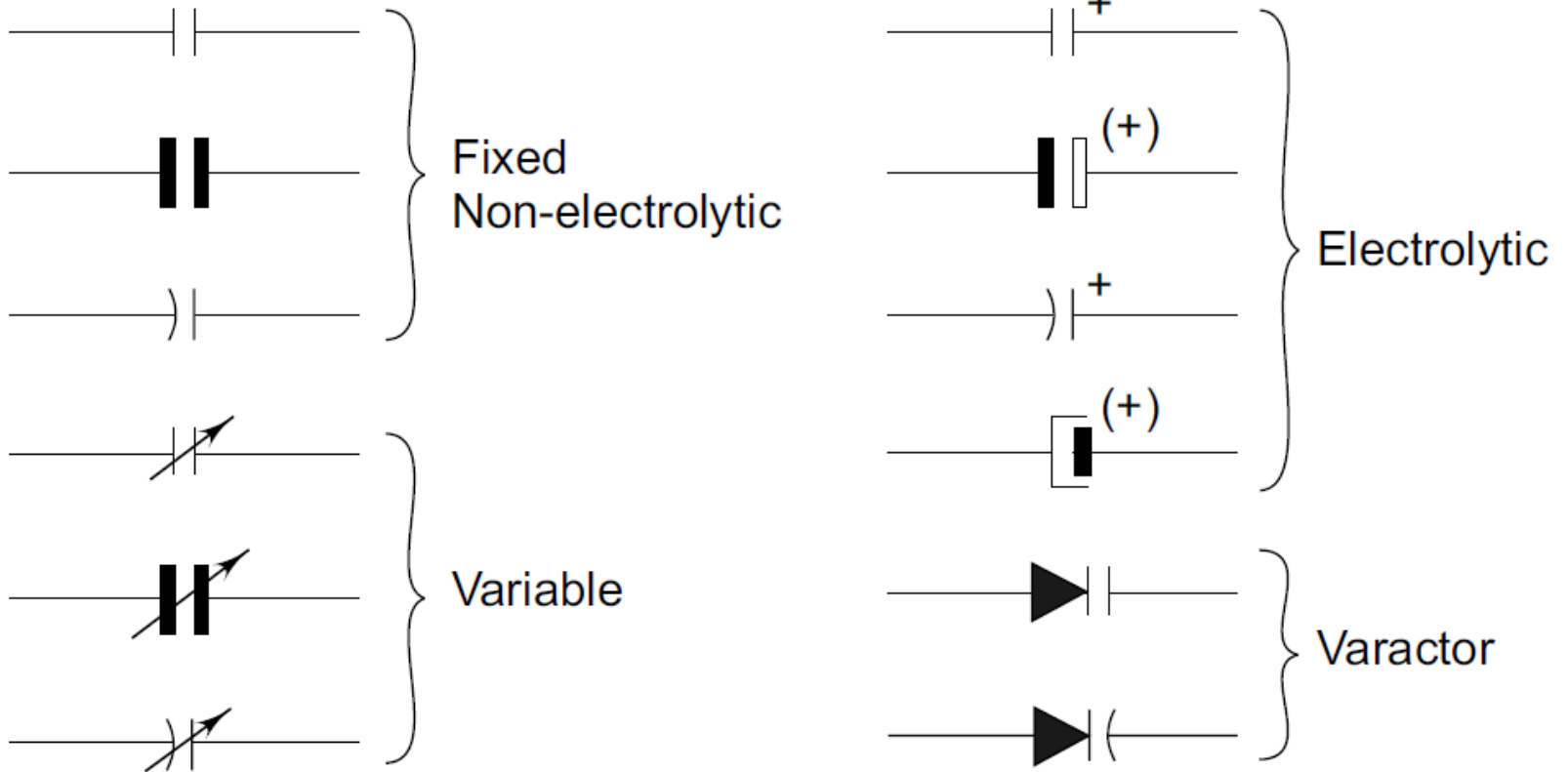


(b) Buried foil type

$$Q = CV$$

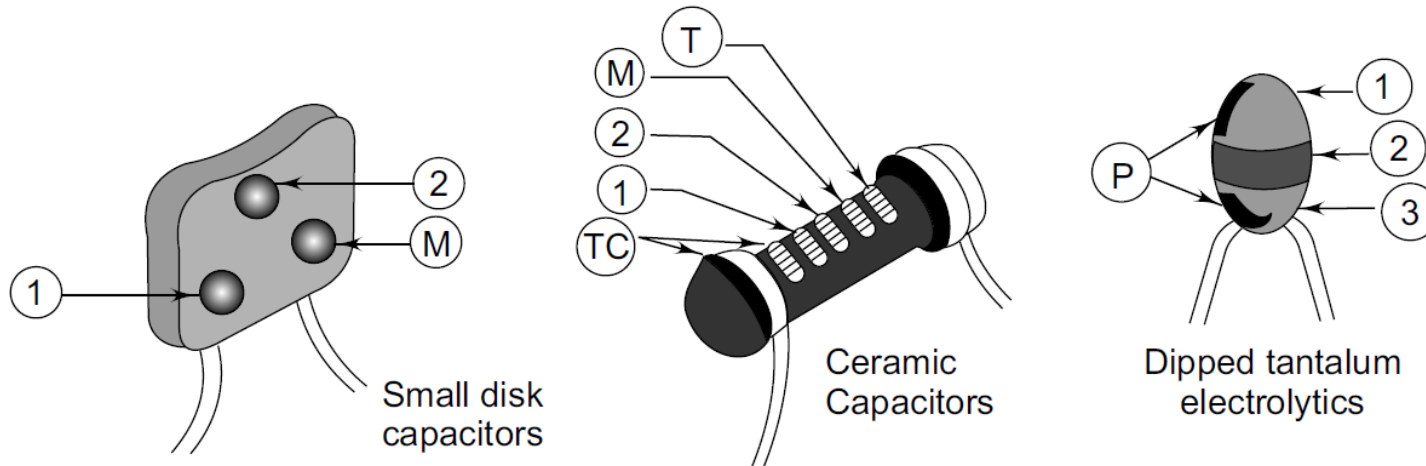
Capacitors (Condensers)

□ Graphical symbols



Capacitors (Condensers)

□ Color code



Colour code

① ② and ③ 1st, 2nd and 3rd significant figs.

Ⓣ and/or Ⓣⓐ Colour code may not be present on some capacitors

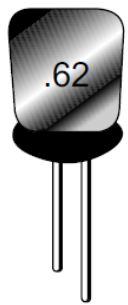
Ⓜ Multiplier Ⓣ Tolerance

Ⓟ Positive (+) polarity and voltage ratings

Ⓣⓐ Temperature coefficient

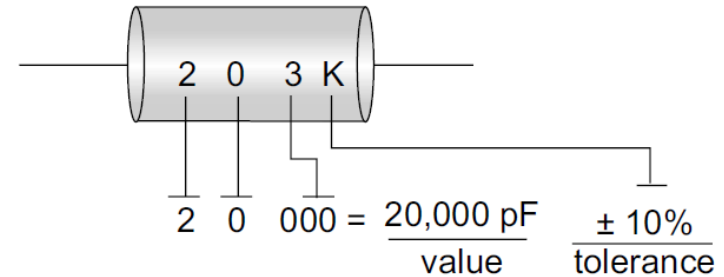
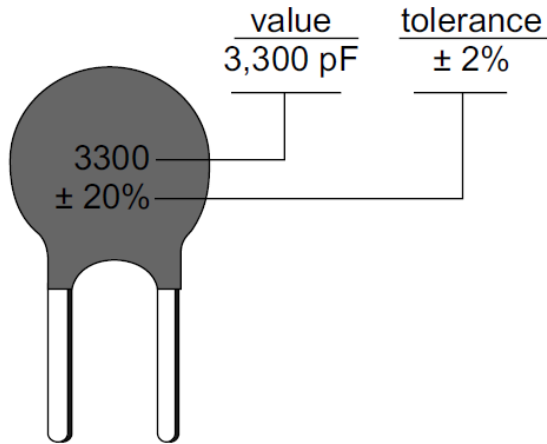
Capacitors (Condensers)

- Code for numbered capacitors



$$= \frac{.62 \mu\text{F}}{\text{value}} \quad \frac{\pm 20\%}{\text{tolerance}}$$

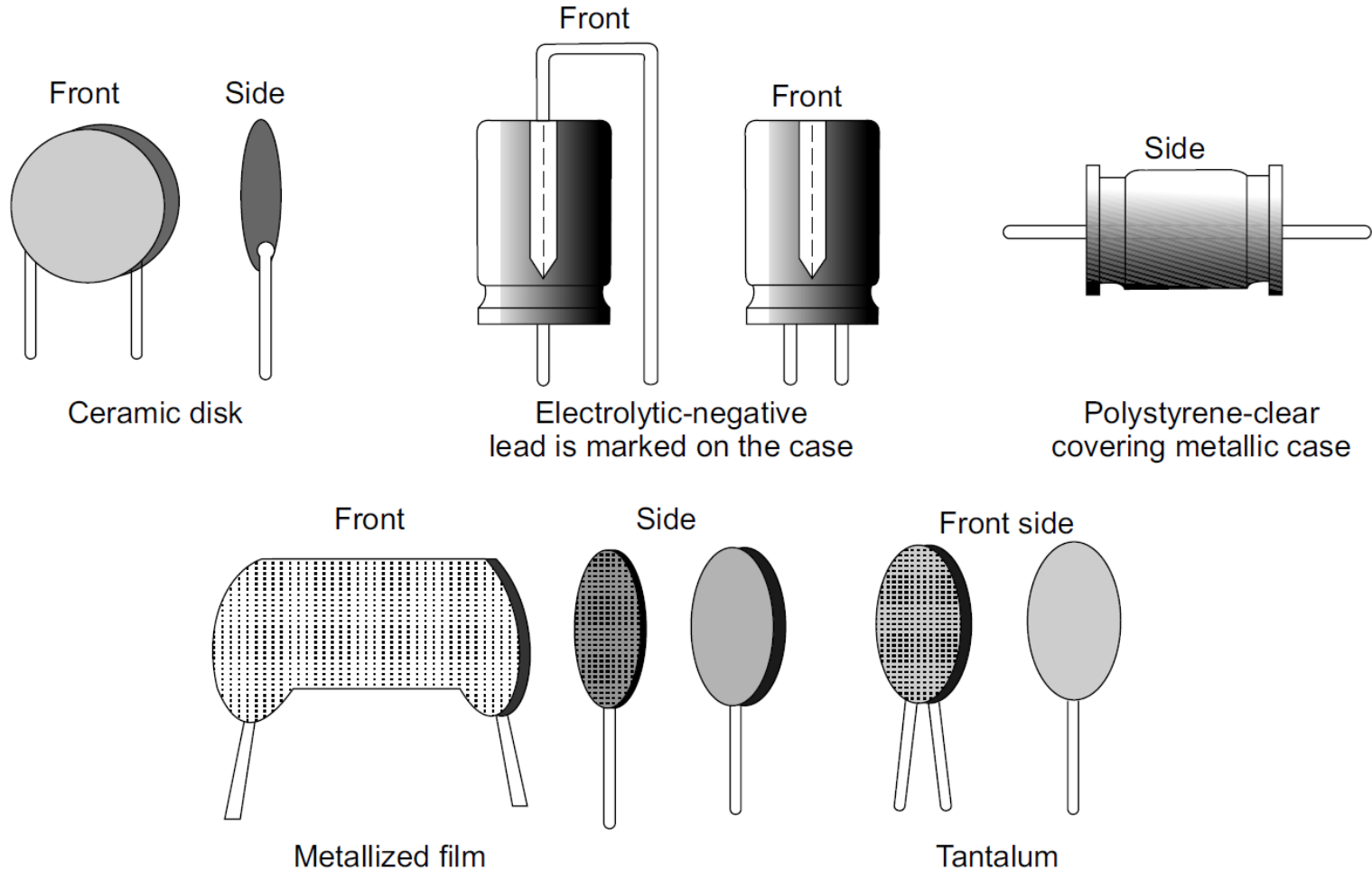
If no tolerance is shown,
the tolerance is $\pm 20\%$



F = $\pm 1\%$, G = $\pm 2\%$, J = $\pm 5\%$, K = $\pm 10\%$, M = $\pm 20\%$ and Z = +80 to -20%

Capacitors (Condensers)

□ Types



Capacitors (Condensers)

□ Paper capacitors

Typical range	:	10 nF to 10 μ F
Typical dc voltage	:	500 V(max.)
Tolerance	:	$\pm 10\%$

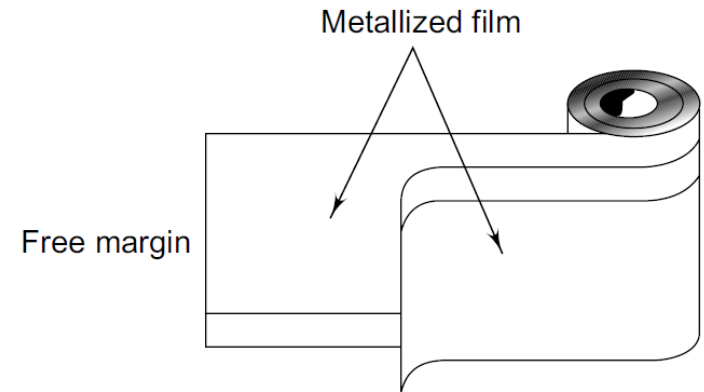
□ Mica capacitors

Typical range	:	5 pF to 10 nF
Typical dc voltage	:	50 to 500 V
Tolerance	:	$\pm 0.5\%$

□ Ceramic capacitors

Typical range	:	(a) Low loss (steatite) 5 pF to 10 nF
		(b) Barium titanate 5 pF to 1 μ F
		(c) Monolithic 1 nF to 47 μ F

Typical voltage range	:	For a and b 60 V to 10 kV
		For c: 60 V to 400 V
Tolerance	:	$\pm 10\%$ to $\pm 20\%$

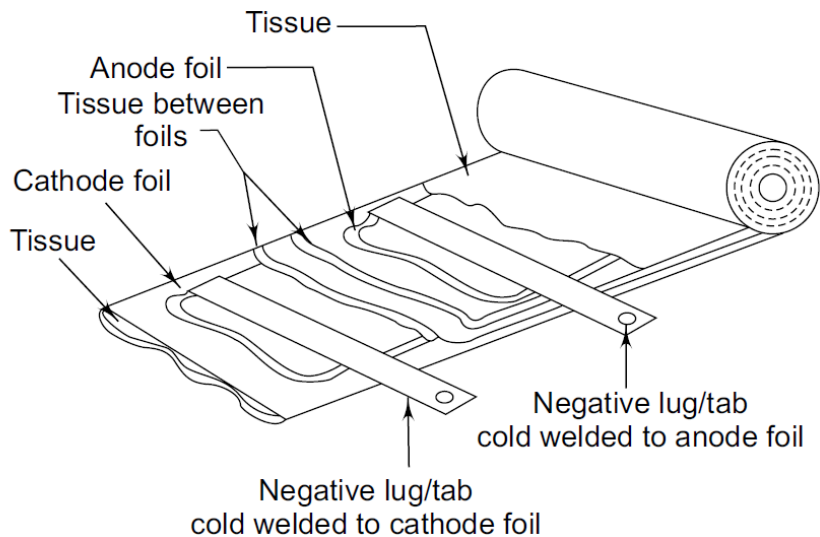


Capacitors (Condensers)

□ Electrolytic capacitors

- Aluminum

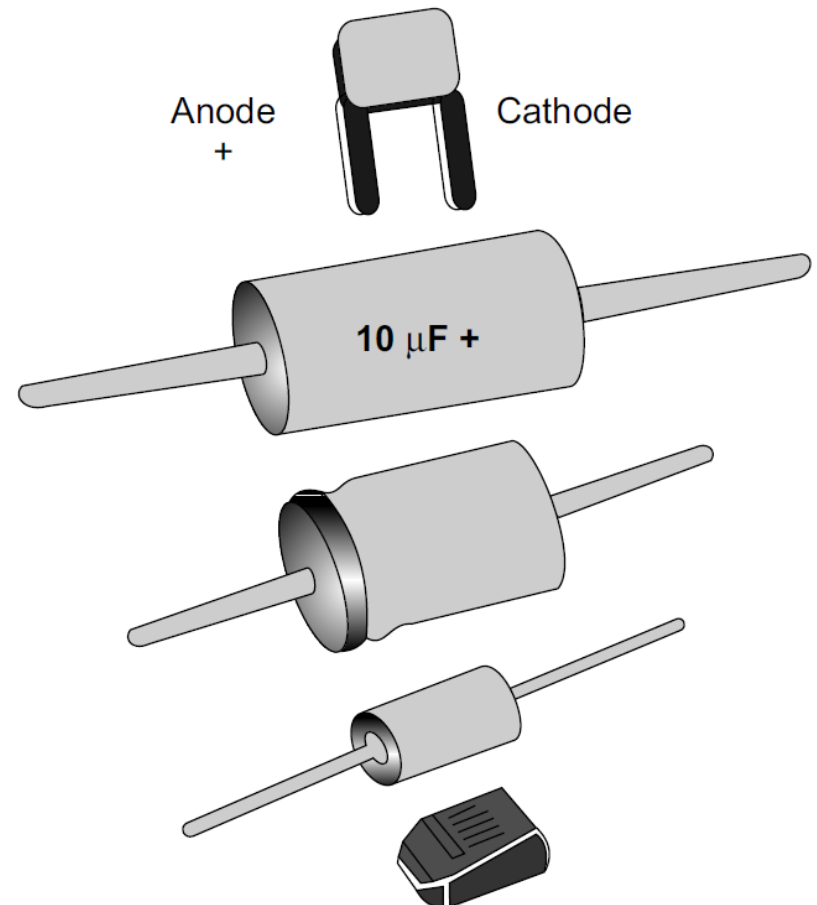
- Tantalum



Polarized capacitors

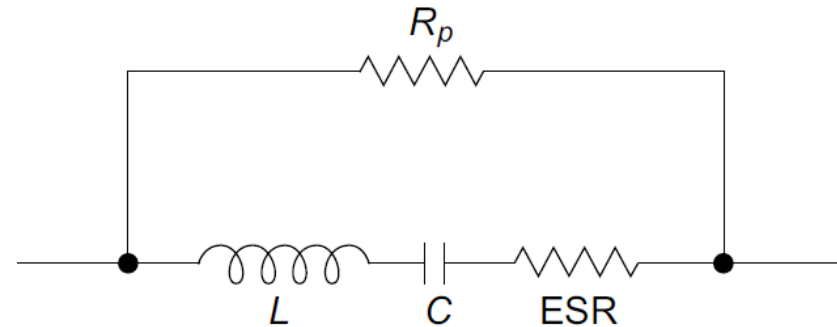
Anode
+

Cathode



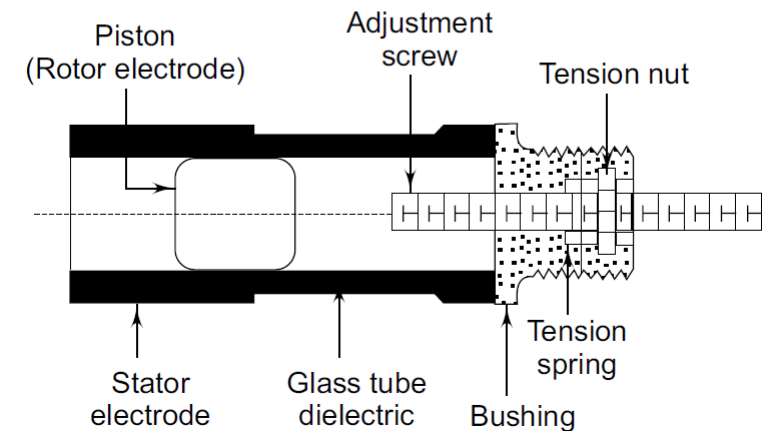
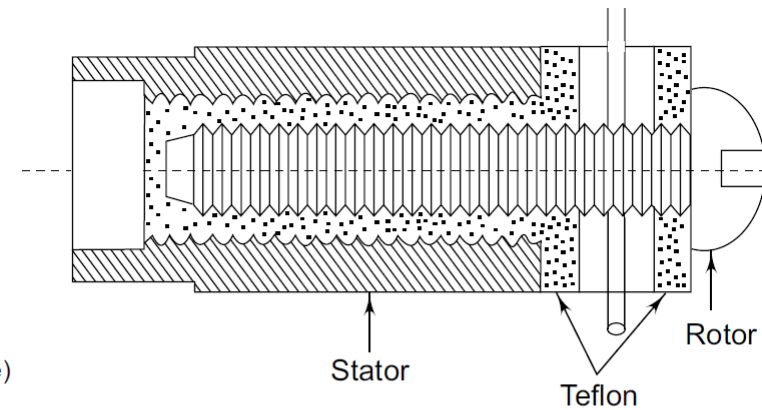
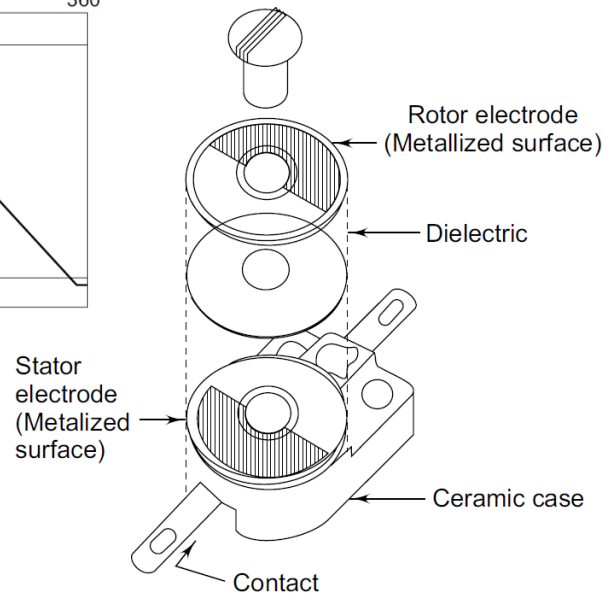
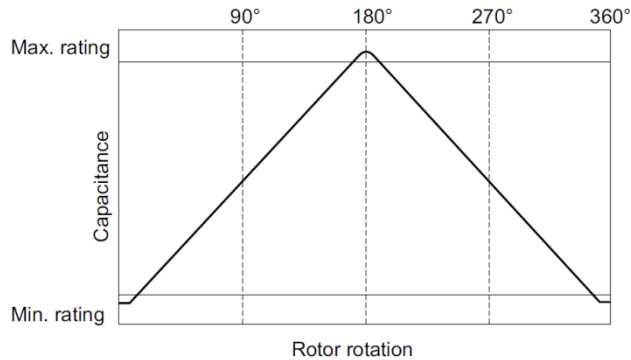
Capacitors (Condensers)

- Capacitance
- Tolerance
- Working Voltage (= $\frac{1}{2}$ breakdown voltage)
- Temperature Coefficient
- DC Leakage
- Parasitic Effects
 - ▣ dissipation factor (DF)= $1/Q$



Variable Capacitors

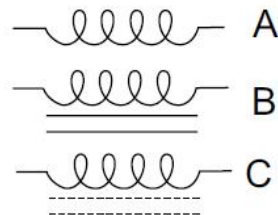
- Variable capacitor has a stator and a rotor to change area
 - Button type
 - Tubular type



Inductors

- A device that resists change in the current through the device.
- Inductors work on the principle that when a current flows in a coil of wire, a magnetic field is produced, which collapses when the current is stopped.
- The collapsing magnetic field produces an electromotive force which tries to maintain the current.

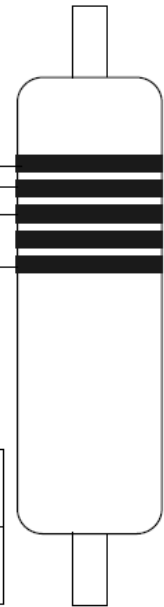
$$e = -L \frac{di}{dt}$$



Inductors

Inductor Band Colour Codes

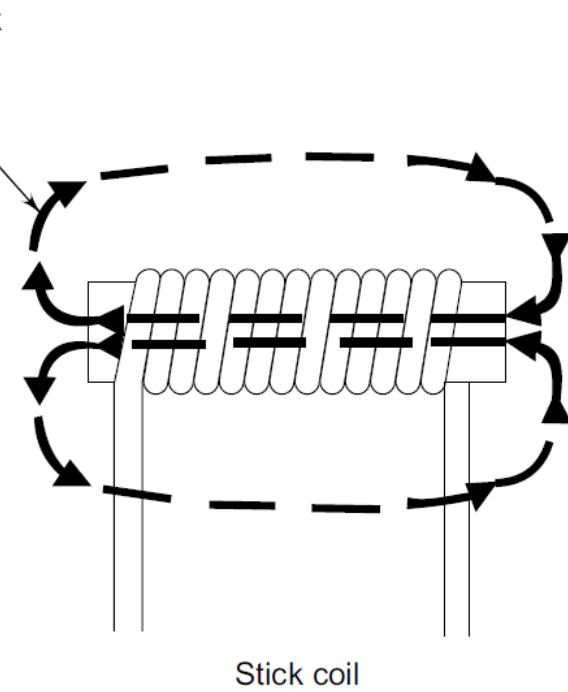
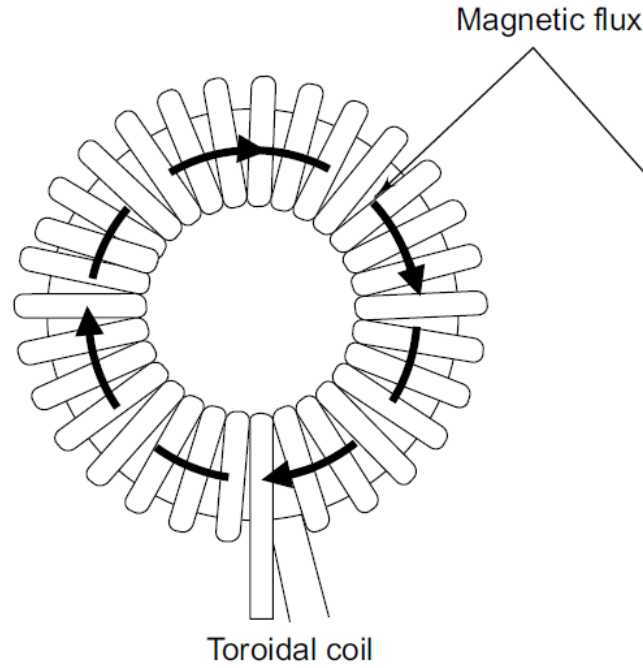
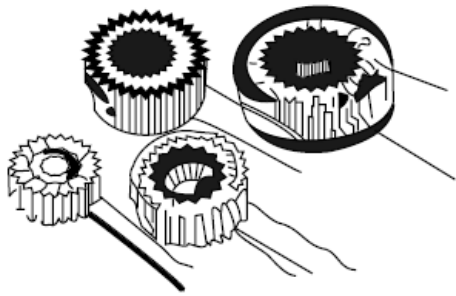
1 st Band (Value)	2 nd Band (Value)	3 rd Band (Multiplier)	4 th Band (tolerance)
Brown 1	Black 0	Black × 1 or no zeros	Red ± 2%
Red 2	Brown 1	Brown × 10 or +1 zero	Gold ± 5%
Orange 3	Red 2	Red × 100 or +2 zeros	Green ± 5%
Yellow 4	Orange 3	Orange × 1k or +3 zeros	Blue ± .25%
Green 5	Yellow 4	Yellow × 10k or +4 zeros	Violet ± .1%
Blue 6	Green 5	Green × 100k or +5 zeros	Gold ± 5%
Violet 7	Blue 6	Blue × 1m or +6 zeros	Silver ± 10%
Grey 8	Violet 7	Gold × .1	
White 9	Grey 8	Silver × .01	
	White 9		



Inductors

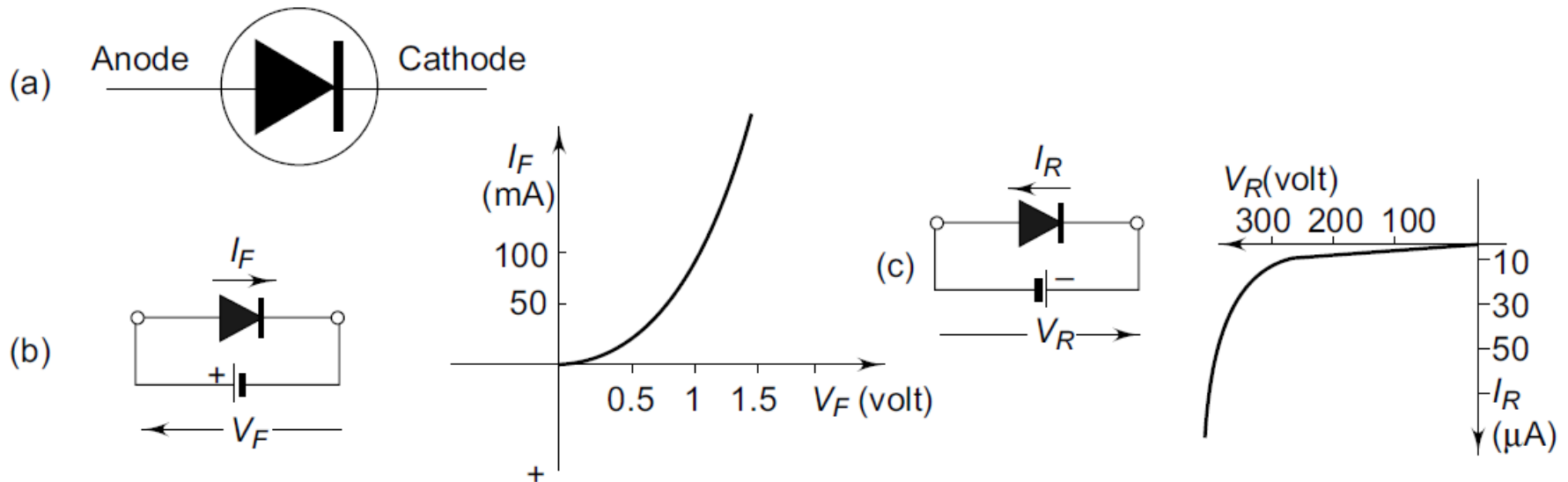
- The primary use of an inductor is filtering.
 - ▣ High current inductors wound around a large core are used in power supply filters
 - ▣ Low current air core inductors are used in signal filters
- Basic components of an inductor are the former (or bobbin), winding wire (with or without separating material) and the core material
 - ▣ Bobbins are normally made of molded plastic
 - ▣ Winding is usually enameled copper wire
 - ▣ Core material can be laminated steel, powdered iron or ferrite – Shape also varies

Inductors

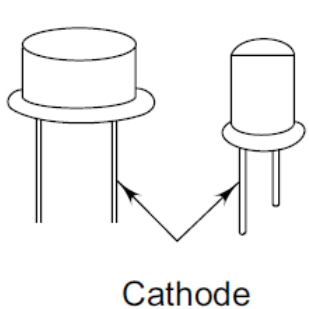
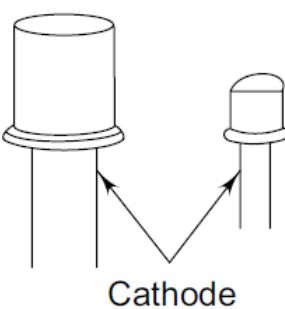
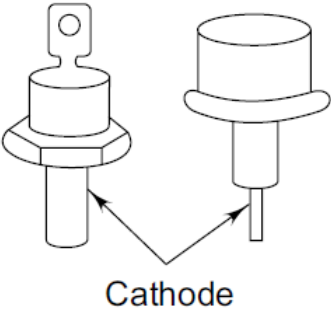
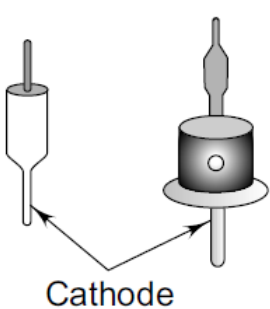
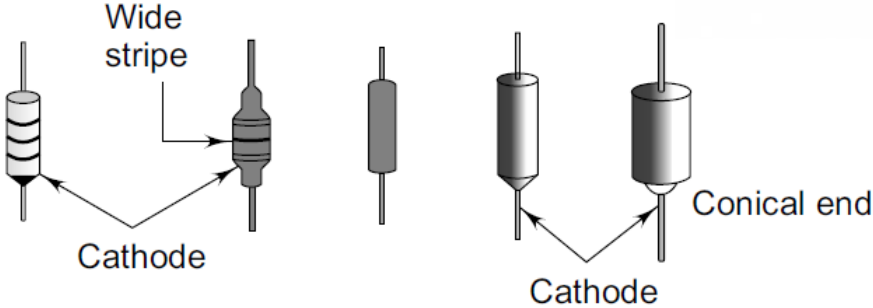
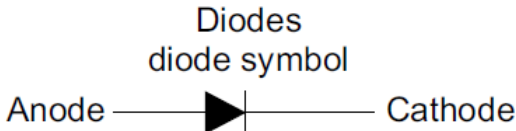
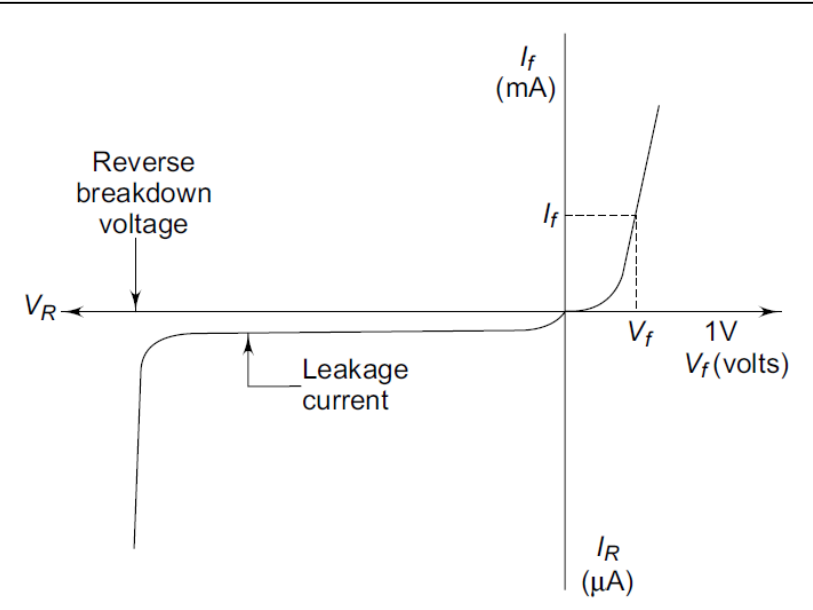


Diodes

- A diode is an active component made of semiconductor material through which the current flows more easily in one direction than in the other

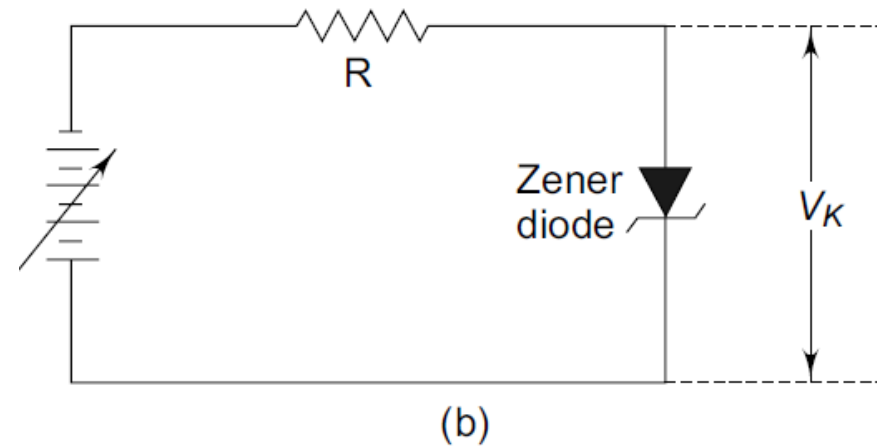
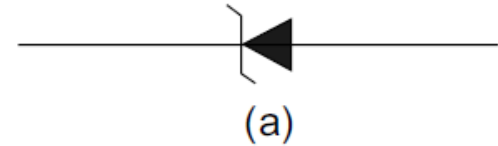


Diodes



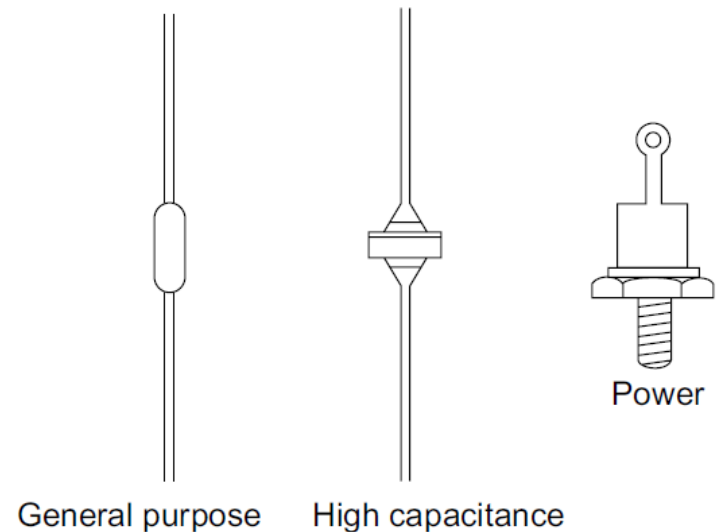
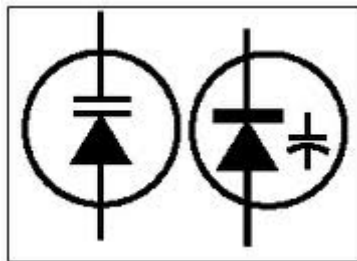
Zener Diodes

- Breakdown avalanche or the Zener voltage
 - ▣ Range from 1 volt to several hundred volts
 - ▣ Behaves like a voltage source in the Zener region
- Distinguish Zener diode from a general purpose diode by being usually labelled with its specified breakdown voltage



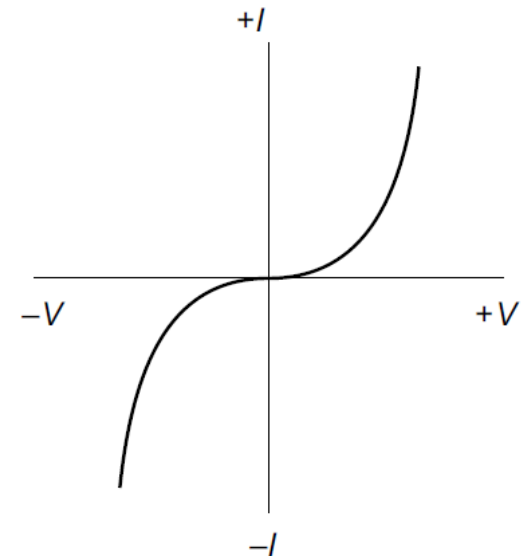
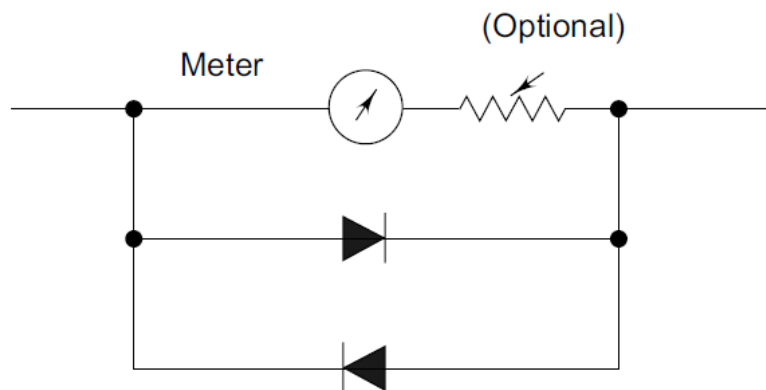
Varactor Diode

- Silicon diode that works as a variable capacitor in response to a range of reverse voltage values
 - ▣ Nominal capacitance values ranging from 1 to 500 pF
 - ▣ Maximum rated operating voltages from 10 to 100 volts



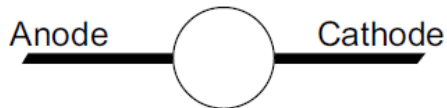
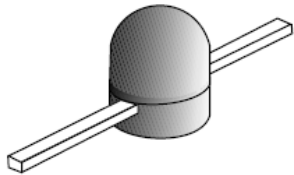
Varistor

- Semiconductor device having voltage-dependent non-linear resistance that drops as applied voltage is increased
- Symmetrical varistor arrangements are used in meter protection circuits

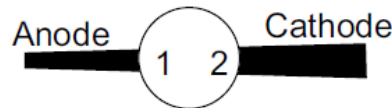
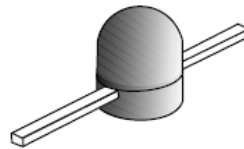


Light Emitting Diodes (LEDs)

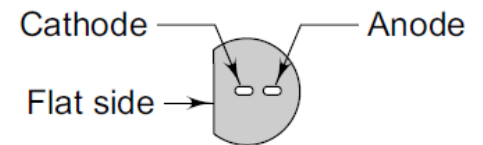
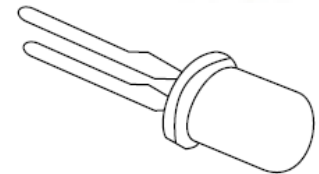
- A LED is basically a p-n junction that emits light when forward biased
 - ▣ Different colors and shapes



(Cathode identified by small plastic protrusion)



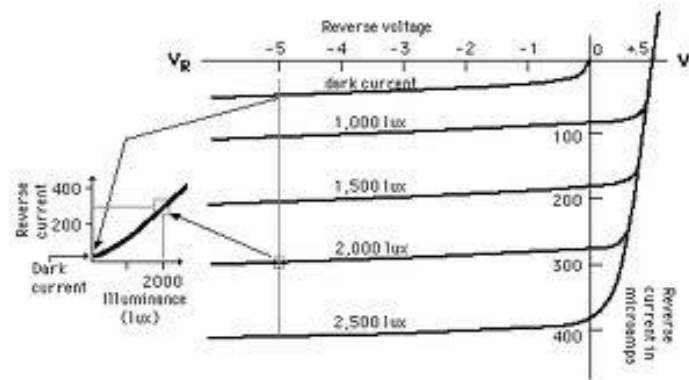
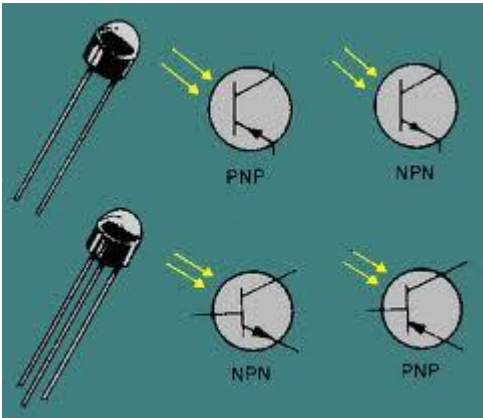
(Cathode identified by larger lead)



(Cathode identified by flat on side of case)

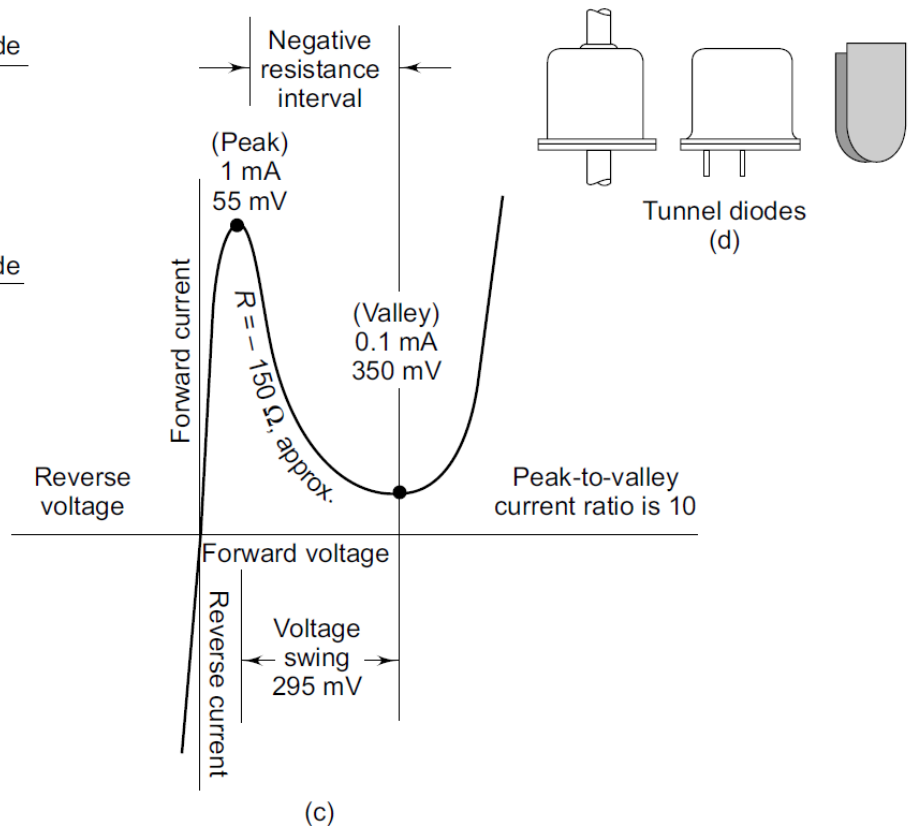
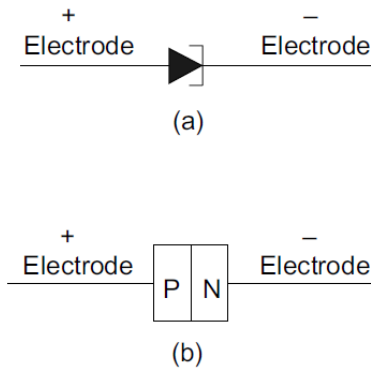
Photodiode

- A photodiode is a solid state device, similar to a conventional diode, except that when light falls on it, it causes the device to conduct
 - ▣ Practically an open circuit in darkness, but conducts a substantial amount of current when exposed to light.



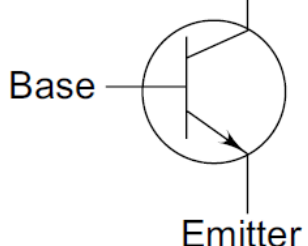
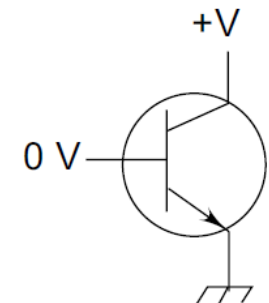
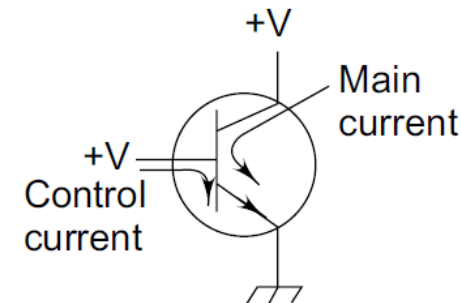
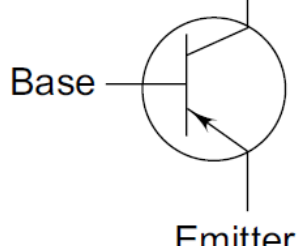
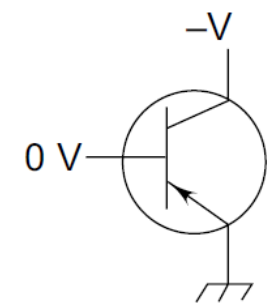
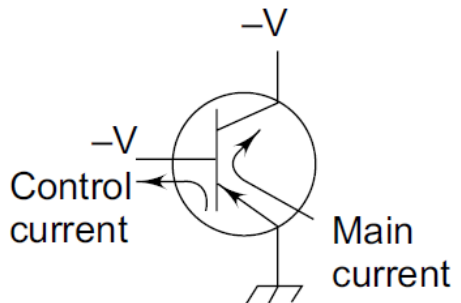
Tunnel Diode (TD)

- A tunnel diode is a p-n junction which exhibits a negative resistance interval

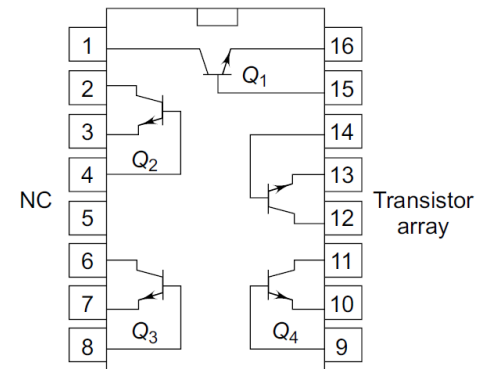
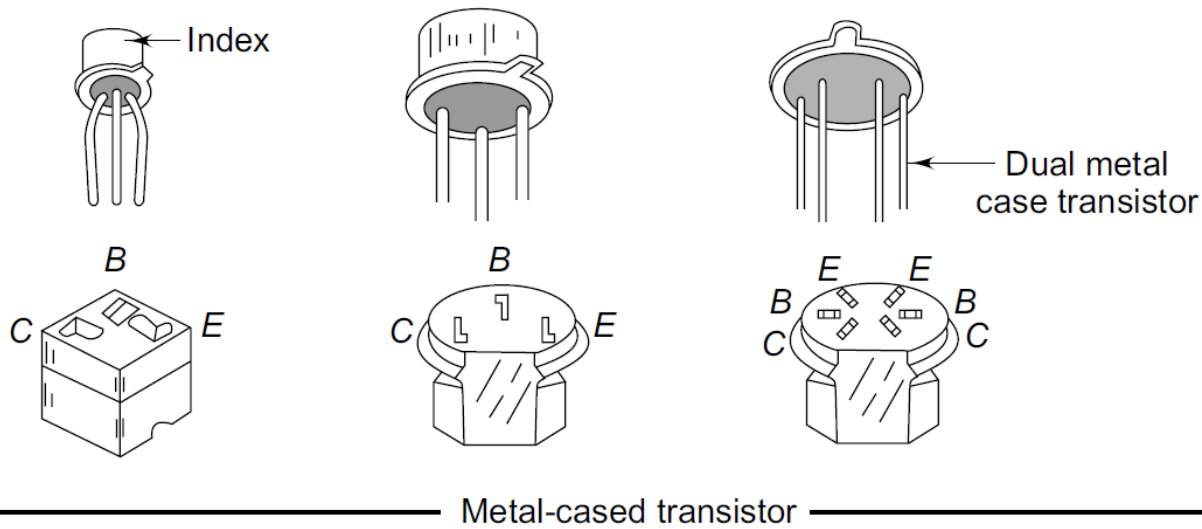
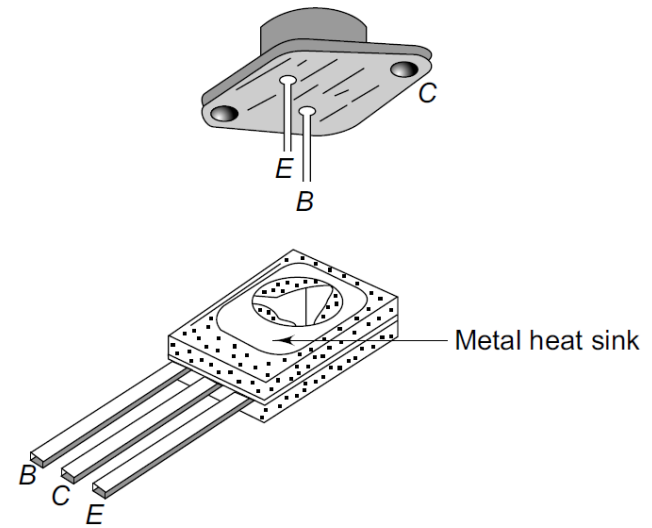
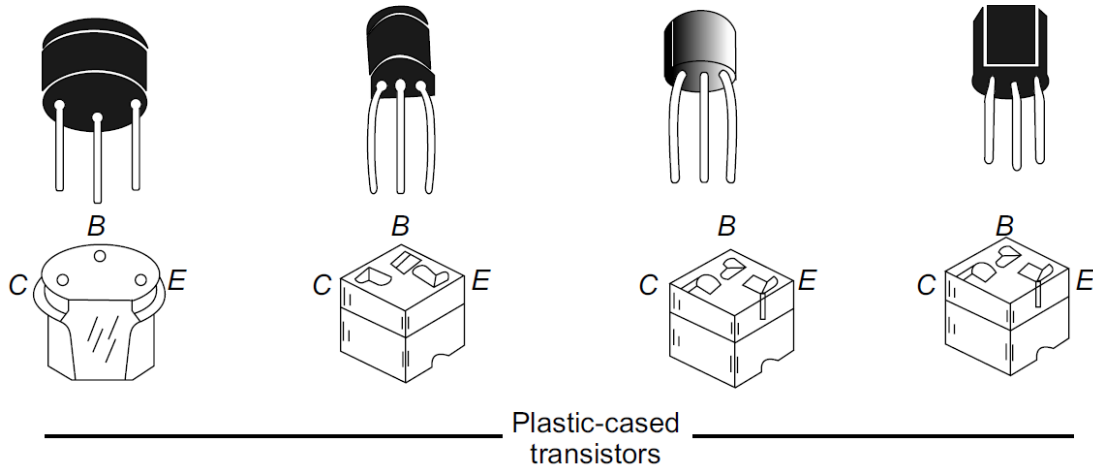


Transistors

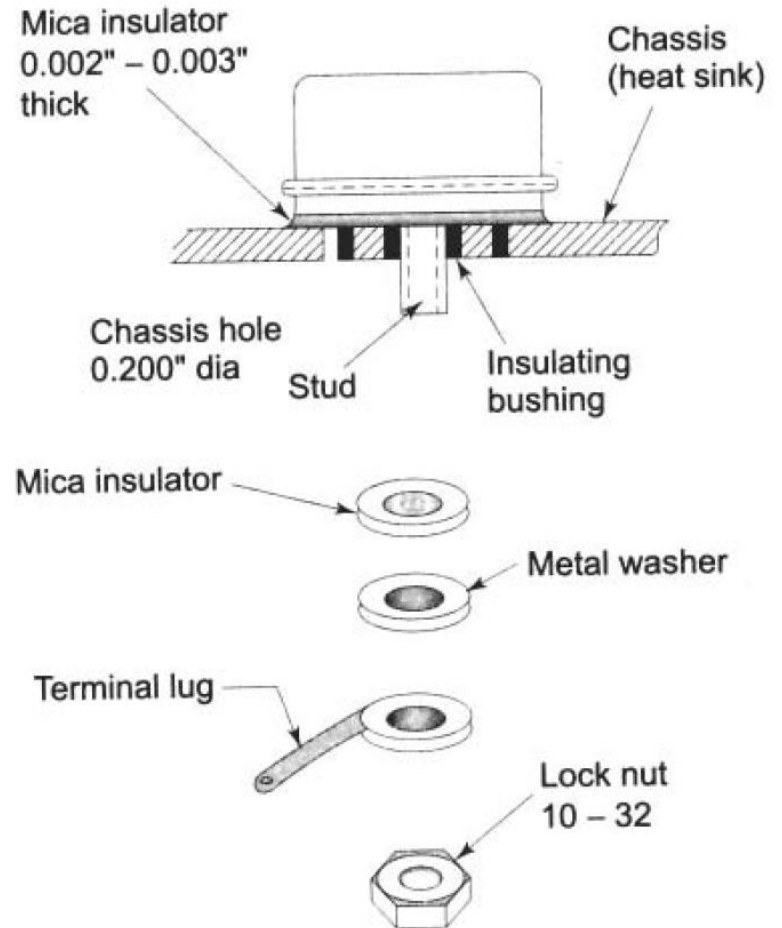
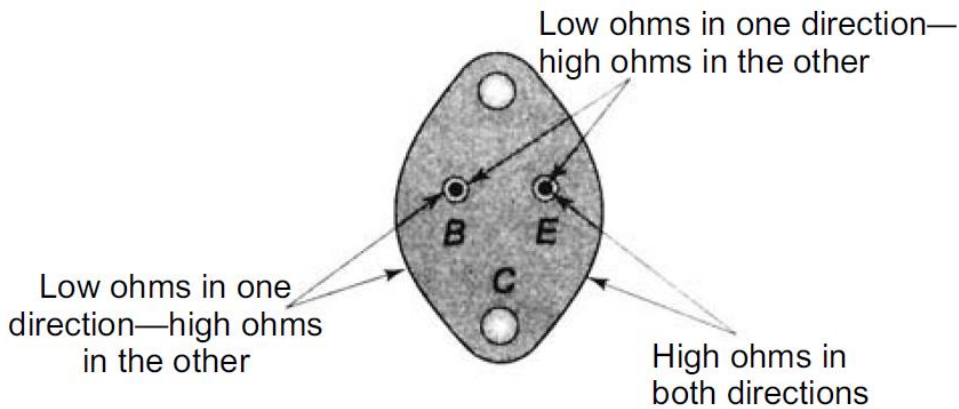
□ Bipolar junction transistors (BJT)

Type	Cutoff	Conduction
<p>NPN</p> <p>Collector</p>  <p>Base</p> <p>Emitter</p>	<p>+V</p>  <p>0 V</p>	<p>+V</p>  <p>Main current</p> <p>+V</p> <p>Control current</p>
<p>PNP</p> <p>Collector</p>  <p>Base</p> <p>Emitter</p>	<p>-V</p>  <p>0 V</p>	<p>-V</p>  <p>Main current</p> <p>-V</p> <p>Control current</p>

Transistors

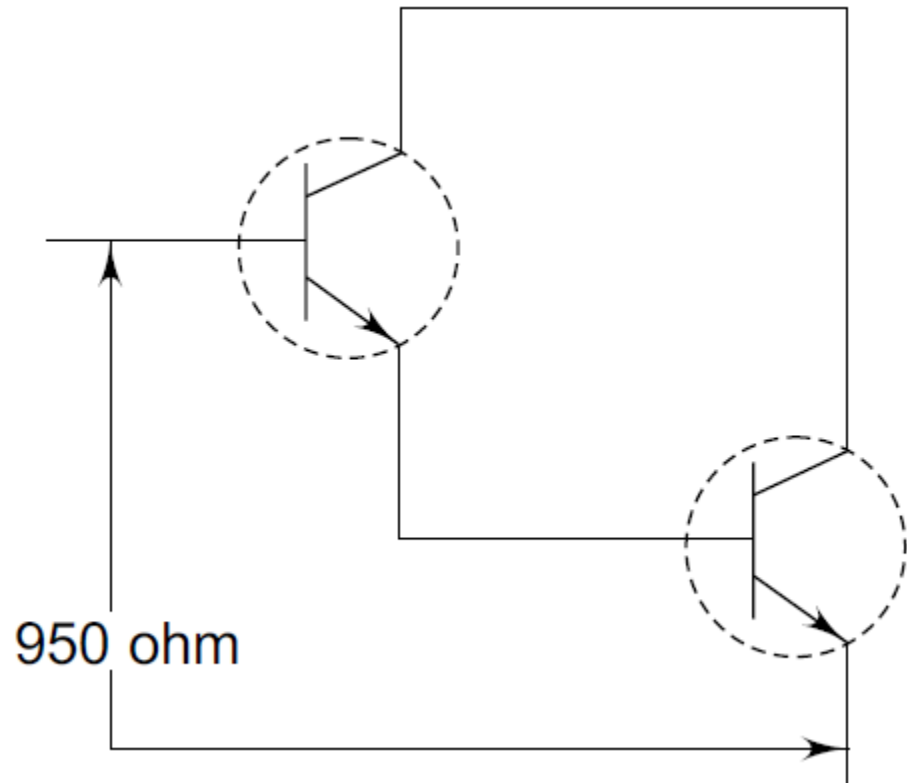
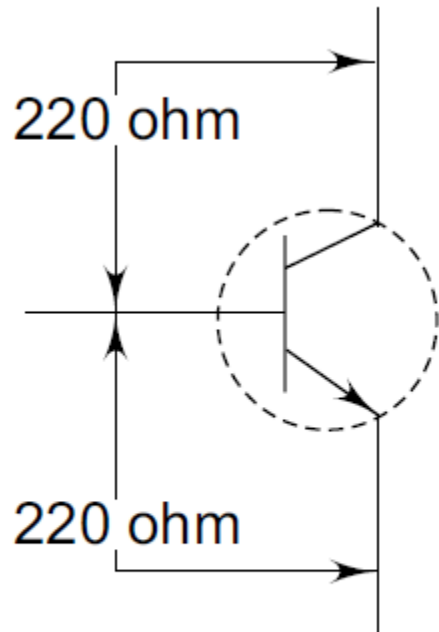


Power Transistors

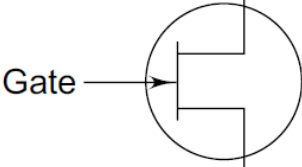
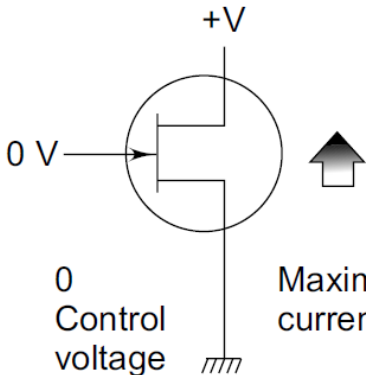
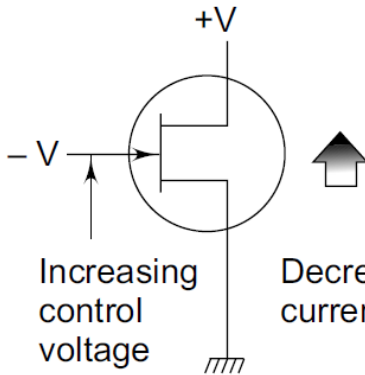
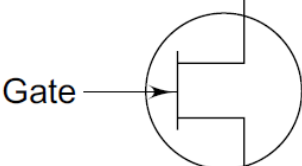
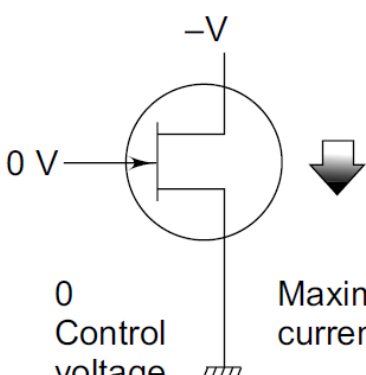
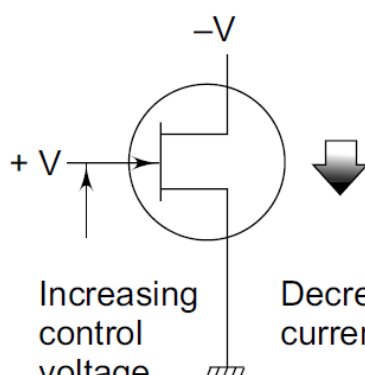


Darlington Pair Transistors

- Higher current gain



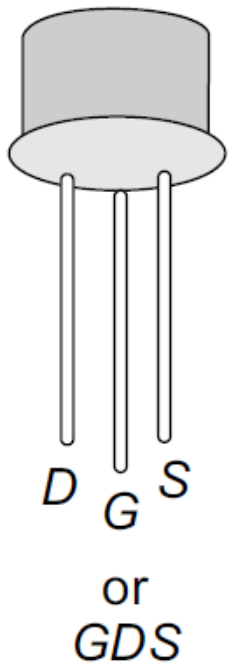
Field-Effect Transistor (FET)

Type		
<p>N - Channel</p>  <p>Drain</p> <p>Source</p> <p>Gate</p>	 <p>+V</p> <p>0 V</p> <p>0 Control voltage</p> <p>Maximum current flow</p>	 <p>+V</p> <p>- V</p> <p>Increasing control voltage</p> <p>Decreases current flow</p>
<p>P - Channel</p>  <p>Drain</p> <p>Source</p> <p>Gate</p>	 <p>-V</p> <p>0 V</p> <p>0 Control voltage</p> <p>Maximum current flow</p>	 <p>-V</p> <p>+ V</p> <p>Increasing control voltage</p> <p>Decreases current flow</p>

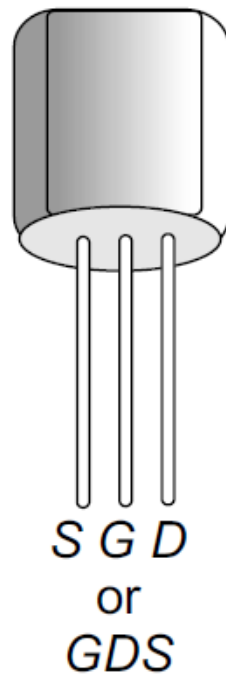
Field-Effect Transistor (FET)

Field effect transistors

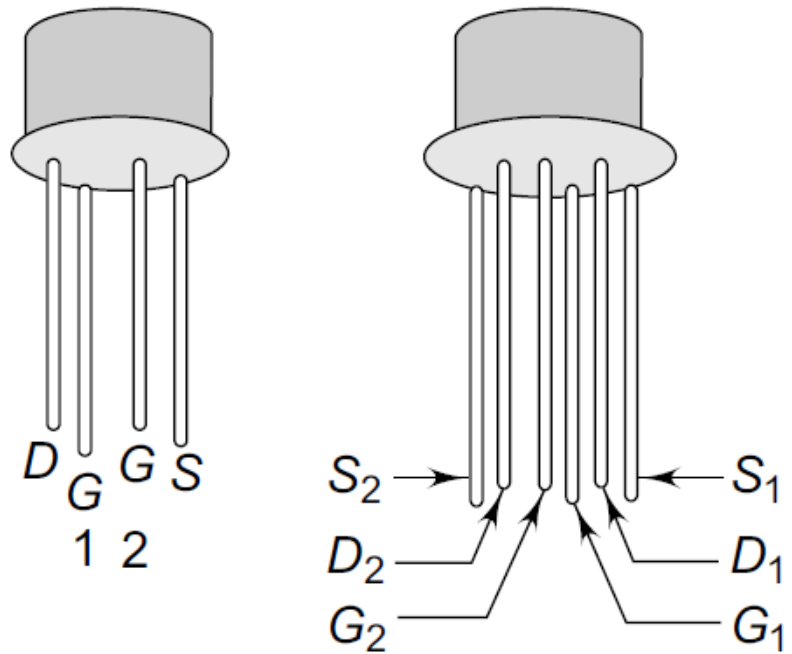
Metal case



Black plastic



Metal case



Transistor Type Numbers

- Joint Electron Device Engineering Council (JEDEC)
 - ▣ Digit, letter, serial number, (suffix),
 - ▣ Letter is always 'N', the serial number runs from 100 to 9999 (arbitrary), optional suffix indicates the gain (hfe) group of the device.

A = low gain

C = high gain

B = medium gain

No suffix = ungrouped (any gain)

Transistor Type Numbers

- Japanese Industrial Standard (JIS)
 - ▣ Digit, two letters, serial number, (suffix)

SA = PNP HF transistor

SB = PNP AF transistor

SC = NPN HF transistor

SD = NPN AF transistor

SJ = P-channel FET/MOSFET

SK = N-channel FET/MOSFET

- ▣ Examples: 2SA1187, 2SB646, 2SC733.

Transistor Type Numbers

- Pro-electron System (European)

- Two letters, (letter), serial number, (suffix)

- First letter: material

A = Germanium (Ge)

B = Silicon (Si)

C = Gallium Arsenide (GaAs)

R = Compound materials

- Second letter: device application

C = Transistor, AF, small signal

D = Transistor, AF, power

F = Transistor, HF, small signal

L = Transistor, HF, power

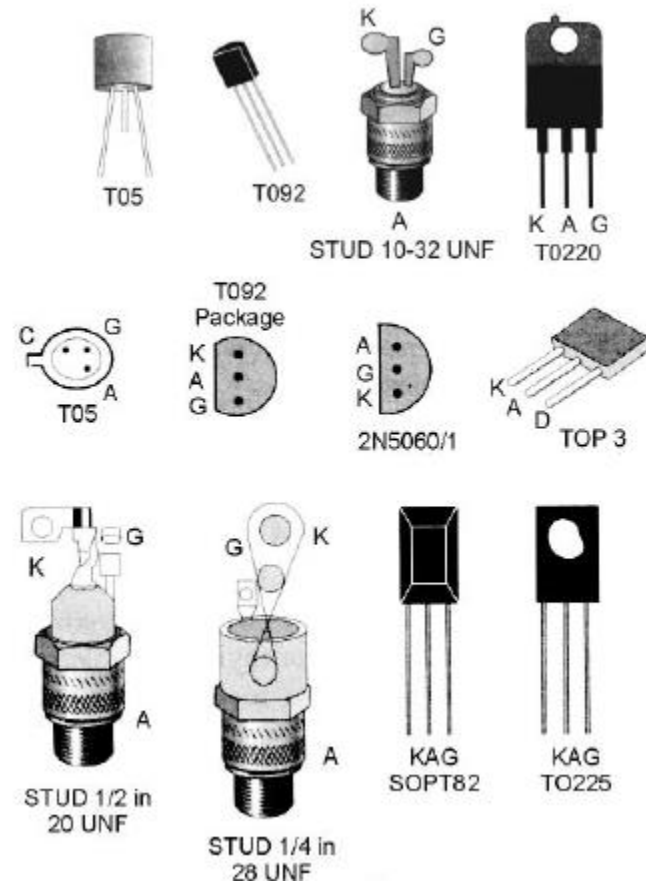
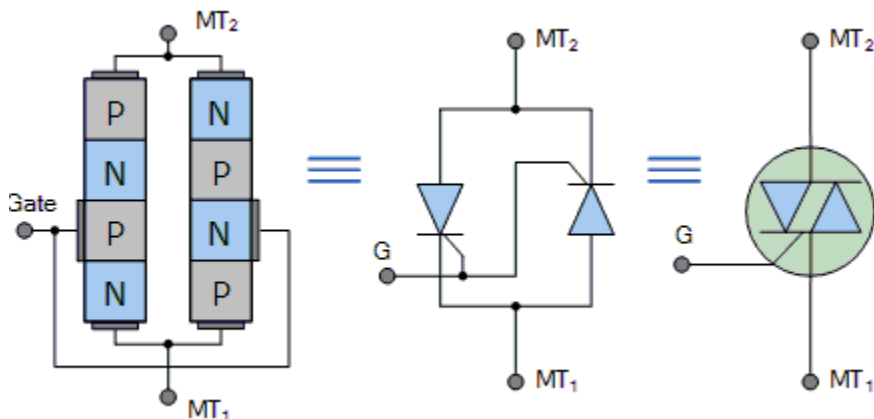
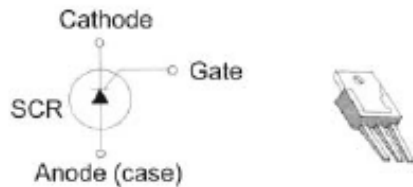
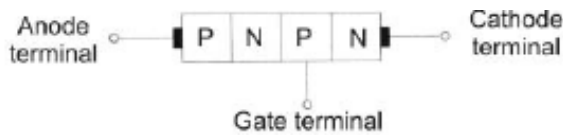
U = Transistor, power, switching

- Suffix: like JEDEC

- Examples: BC108A, BAW68, BF239, BFY51

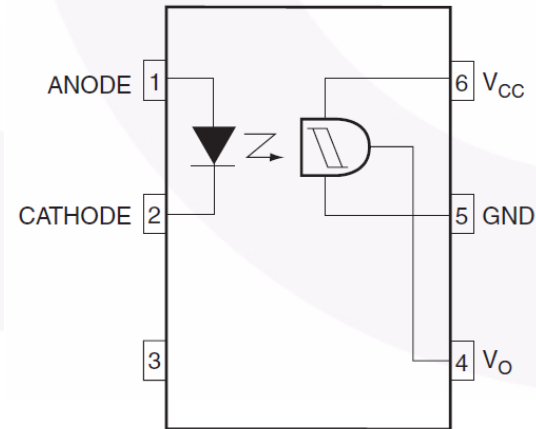
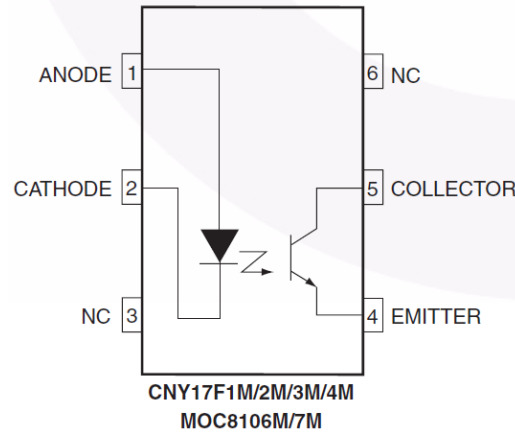
Thyristors

- Silicon-controlled rectifier (SCR)
- Triac (bidirectional triode thyristor)



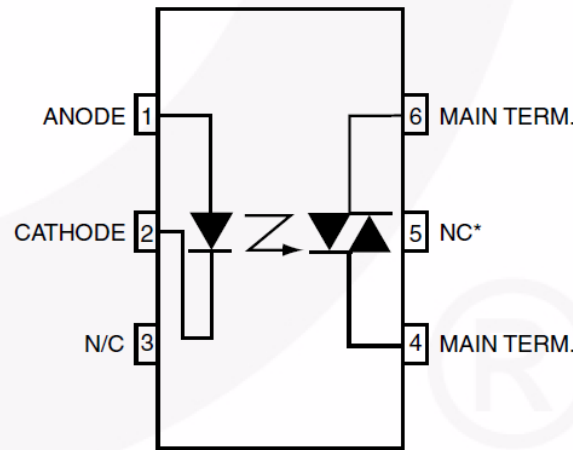
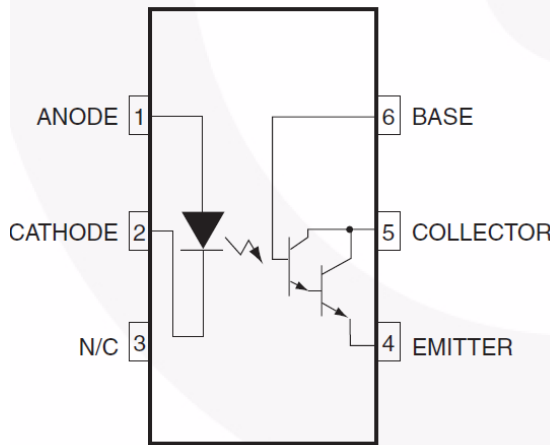
Optocoupler/Optoisolator/Optotriac

- Digital
- Transistor
- Triac/SCR



Truth Table

Input	Output
H	L
L	H



*DO NOT CONNECT (TRIAC SUBSTRATE)

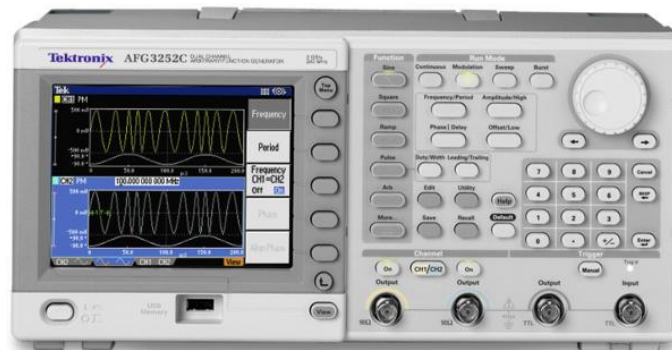


Oscilloscope

- ❑ Cathode ray oscilloscope (CRO) (old – analog)
- ❑ Digital storage oscilloscope (DSO) (new – digital)



Function Generator



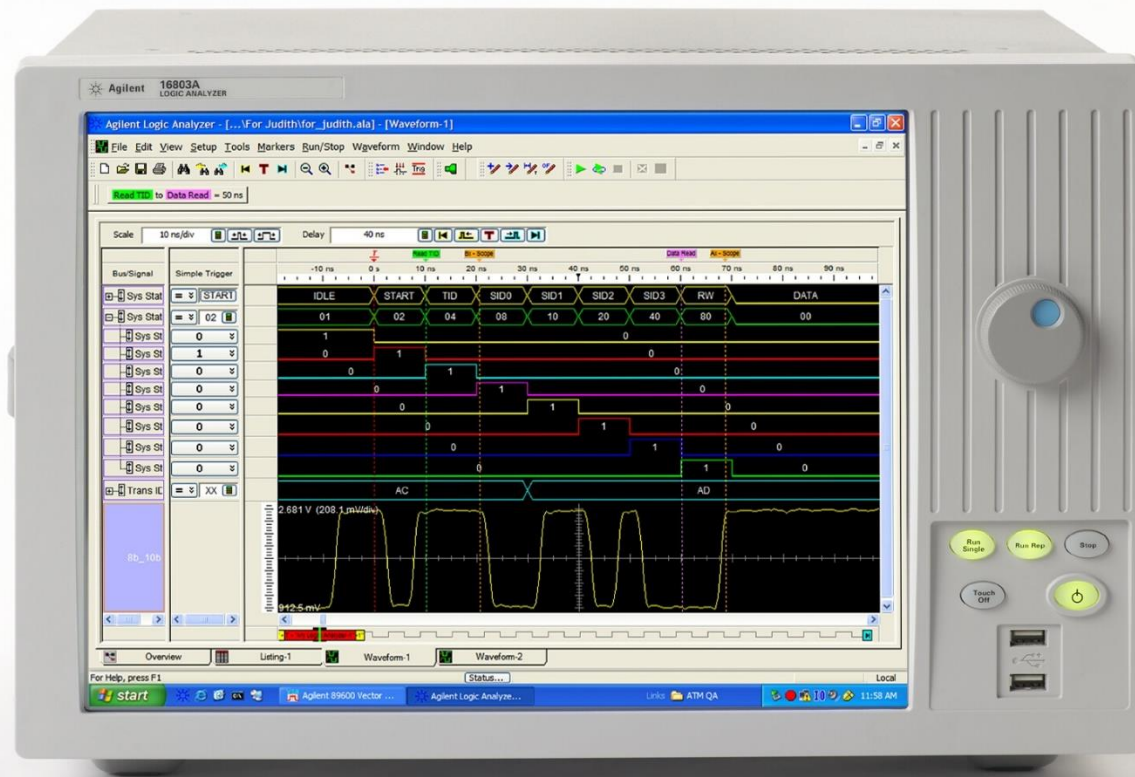
Power Supply



Multimeter



Logic Analyzer



Cables / Connectors

- ❑ Banana connectors
- ❑ Alligator (Crocodile) connectors
- ❑ BNC connector
- ❑ Oscilloscope probe
- ❑ Multimeter test leads



Suggested Readings and Assignments

- Laboratory Introduction handout on class web site
- Lab #1 requirements posted on web site